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# 74HC4053; 74HCT4053

Triple 2-channel analog multiplexer/demultiplexer

Rev. 04 — 9 May 2006

Product data sheet

## 1. General description

The 74HC4053; 74HCT4053 is a high-speed Si-gate CMOS device and is pin compatible with the HEF4053B. It is specified in compliance with JEDEC standard no. 7A.

The 74HC4053; 74HCT4053 is triple 2-channel analog multiplexer/demultiplexer with a common enable input ( $\bar{E}$ ). Each multiplexer/demultiplexer has two independent inputs/outputs (nY0 and nY1), a common input/output (nZ) and three digital select inputs (Sn).

With  $\bar{E}$  LOW, one of the two switches is selected (low-impedance ON-state) by S1 to S3. With  $\bar{E}$  HIGH, all switches are in the high-impedance OFF-state, independent of S1 to S3.

$V_{CC}$  and GND are the supply voltage pins for the digital control inputs (S1 to S3 and  $\bar{E}$ ). The  $V_{CC}$  to GND ranges are 2.0 V to 10.0 V for 74HC4053 and 4.5 V to 5.5 V for 74HCT4053. The analog inputs/outputs (nY0 and nY1, and nZ) can swing between  $V_{CC}$  as a positive limit and  $V_{EE}$  as a negative limit.  $V_{CC} - V_{EE}$  may not exceed 10.0 V.

For operation as a digital multiplexer/demultiplexer,  $V_{EE}$  is connected to GND (typically ground).

## 2. Features

- Low ON resistance:
  - ◆ 80  $\Omega$  (typical) at  $V_{CC} - V_{EE} = 4.5$  V
  - ◆ 70  $\Omega$  (typical) at  $V_{CC} - V_{EE} = 6.0$  V
  - ◆ 60  $\Omega$  (typical) at  $V_{CC} - V_{EE} = 9.0$  V
- Logic level translation:
  - ◆ To enable 5 V logic to communicate with  $\pm 5$  V analog signals
- Typical 'break before make' built in
- Complies with JEDEC standard no. 7A
- ESD protection:
  - ◆ HBM EIA/JESD22-A114-C exceeds 2000 V
  - ◆ MM EIA/JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from  $-40$  °C to  $+85$  °C and from  $-40$  °C to  $+125$  °C

**PHILIPS**

### 3. Applications

- Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating

### 4. Quick reference data

**Table 1: Quick reference data**

$V_{EE} = GND = 0\text{ V}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$ ;  $t_r = t_f = 6\text{ ns}$ .

| Symbol                   | Parameter                     | Conditions                                                                 | Min | Typ | Max | Unit |
|--------------------------|-------------------------------|----------------------------------------------------------------------------|-----|-----|-----|------|
| <b>74HC4053</b>          |                               |                                                                            |     |     |     |      |
| $t_{PZH}$ ,<br>$t_{PZL}$ | turn-ON time                  | $C_L = 15\text{ pF}$ ; $R_L = 1\text{ k}\Omega$ ;<br>$V_{CC} = 5\text{ V}$ |     |     |     |      |
|                          | $\bar{E}$ to $V_{OS}$         |                                                                            | -   | 17  | -   | ns   |
|                          | Sn to $V_{OS}$                |                                                                            | -   | 21  | -   | ns   |
| $t_{PHZ}$ ,<br>$t_{PLZ}$ | turn-OFF time                 | $C_L = 15\text{ pF}$ ; $R_L = 1\text{ k}\Omega$ ;<br>$V_{CC} = 5\text{ V}$ |     |     |     |      |
|                          | $\bar{E}$ to $V_{OS}$         |                                                                            | -   | 18  | -   | ns   |
|                          | Sn to $V_{OS}$                |                                                                            | -   | 17  | -   | ns   |
| $C_i$                    | input capacitance             |                                                                            | -   | 3.5 | -   | pF   |
| $C_S$                    | switch capacitance            |                                                                            |     |     |     |      |
|                          | independent I/O (nYn)         |                                                                            | -   | 5   | -   | pF   |
|                          | common I/O (nZ)               |                                                                            | -   | 8   | -   | pF   |
| $C_{PD}$                 | power dissipation capacitance | per switch; $V_I = GND$ to $V_{CC}$                                        | [1] | -   | 36  | pF   |
| <b>74HCT4053</b>         |                               |                                                                            |     |     |     |      |
| $t_{PZH}$ ,<br>$t_{PZL}$ | turn-ON time                  | $C_L = 15\text{ pF}$ ; $R_L = 1\text{ k}\Omega$ ;<br>$V_{CC} = 5\text{ V}$ |     |     |     |      |
|                          | $\bar{E}$ to $V_{OS}$         |                                                                            | -   | 23  | -   | ns   |
|                          | Sn to $V_{OS}$                |                                                                            | -   | 21  | -   | ns   |
| $t_{PHZ}$ ,<br>$t_{PLZ}$ | turn-OFF time                 | $C_L = 15\text{ pF}$ ; $R_L = 1\text{ k}\Omega$ ;<br>$V_{CC} = 5\text{ V}$ |     |     |     |      |
|                          | $\bar{E}$ to $V_{OS}$         |                                                                            | -   | 20  | -   | ns   |
|                          | Sn to $V_{OS}$                |                                                                            | -   | 19  | -   | ns   |
| $C_i$                    | input capacitance             |                                                                            | -   | 3.5 | -   | pF   |
| $C_S$                    | switch capacitance            |                                                                            |     |     |     |      |
|                          | independent I/O (nYn)         |                                                                            | -   | 5   | -   | pF   |
|                          | common I/O(nZ)                |                                                                            | -   | 8   | -   | pF   |
| $C_{PD}$                 | power dissipation capacitance | per switch; $V_I = GND$ to $(V_{CC} - 1.5\text{ V})$                       | [1] | -   | 36  | pF   |

[1]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ).

$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum \{(C_L + C_S) \times V_{CC}^2 \times f_o\}$  where:

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

$\sum \{(C_L + C_S) \times V_{CC}^2 \times f_o\}$  = sum of outputs;

$C_L$  = output load capacitance in pF;  
 $C_S$  = maximum switch capacitance in pF;  
 $V_{CC}$  = supply voltage in V.

## 5. Ordering information

Table 2: Ordering information

| Type number      | Package           |          |                                                                                                                                |          |
|------------------|-------------------|----------|--------------------------------------------------------------------------------------------------------------------------------|----------|
|                  | Temperature range | Name     | Description                                                                                                                    | Version  |
| <b>74HC4053</b>  |                   |          |                                                                                                                                |          |
| 74HC4053N        | −40 °C to +125 °C | DIP16    | plastic dual in-line package; 16 leads (300 mil); long body                                                                    | SOT38-4  |
| 74HC4053D        | −40 °C to +125 °C | SO16     | plastic small outline package; 16 leads; body width 3.9 mm                                                                     | SOT109-1 |
| 74HC4053DB       | −40 °C to +125 °C | SSOP16   | plastic shrink small outline package; 16 leads; body width 5.3 mm                                                              | SOT338-1 |
| 74HC4053PW       | −40 °C to +125 °C | TSSOP16  | plastic thin shrink small outline package; 16 leads; body width 4.4 mm                                                         | SOT403-1 |
| 74HC4053BQ       | −40 °C to +125 °C | DHVQFN16 | plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm | SOT763-1 |
| <b>74HCT4053</b> |                   |          |                                                                                                                                |          |
| 74HCT4053N       | −40 °C to +125 °C | DIP16    | plastic dual in-line package; 16 leads (300 mil); long body                                                                    | SOT38-4  |
| 74HCT4053D       | −40 °C to +125 °C | SO16     | plastic small outline package; 16 leads; body width 3.9 mm                                                                     | SOT109-1 |
| 74HCT4053DB      | −40 °C to +125 °C | SSOP16   | plastic shrink small outline package; 16 leads; body width 5.3 mm                                                              | SOT338-1 |
| 74HCT4053PW      | −40 °C to +125 °C | TSSOP16  | plastic thin shrink small outline package; 16 leads; body width 4.4 mm                                                         | SOT403-1 |
| 74HCT4053BQ      | −40 °C to +125 °C | DHVQFN16 | plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm | SOT763-1 |

6. Functional diagram

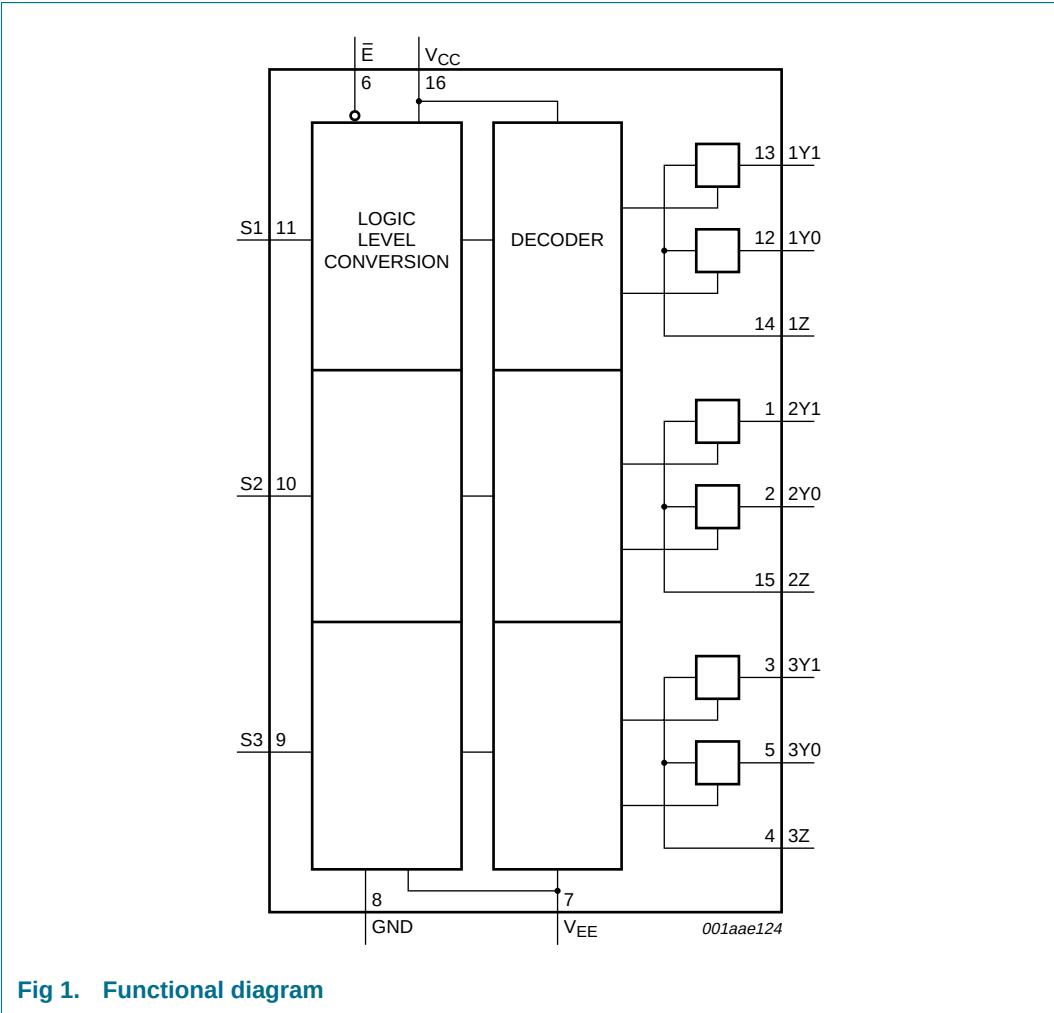


Fig 1. Functional diagram

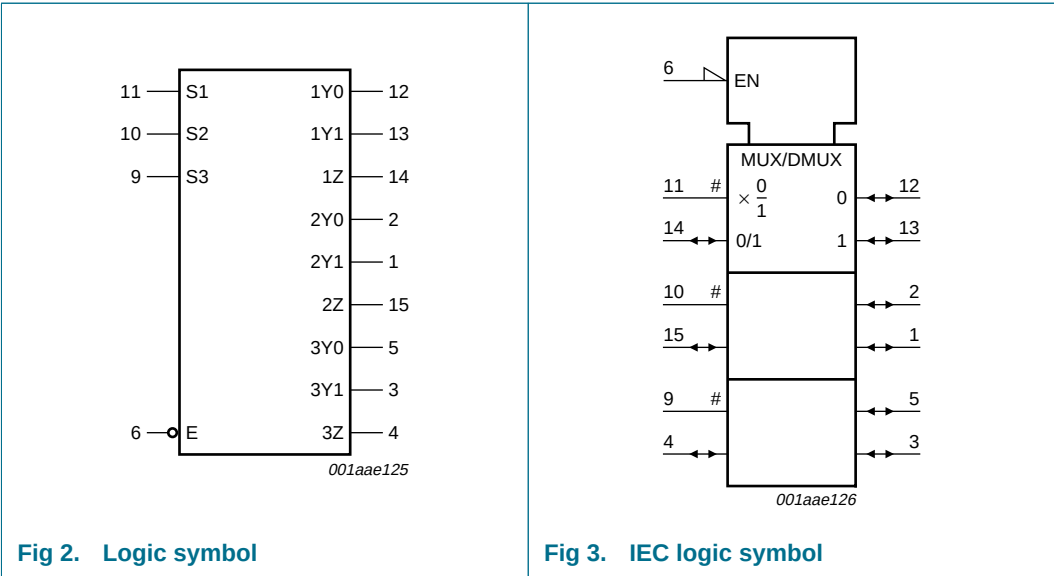
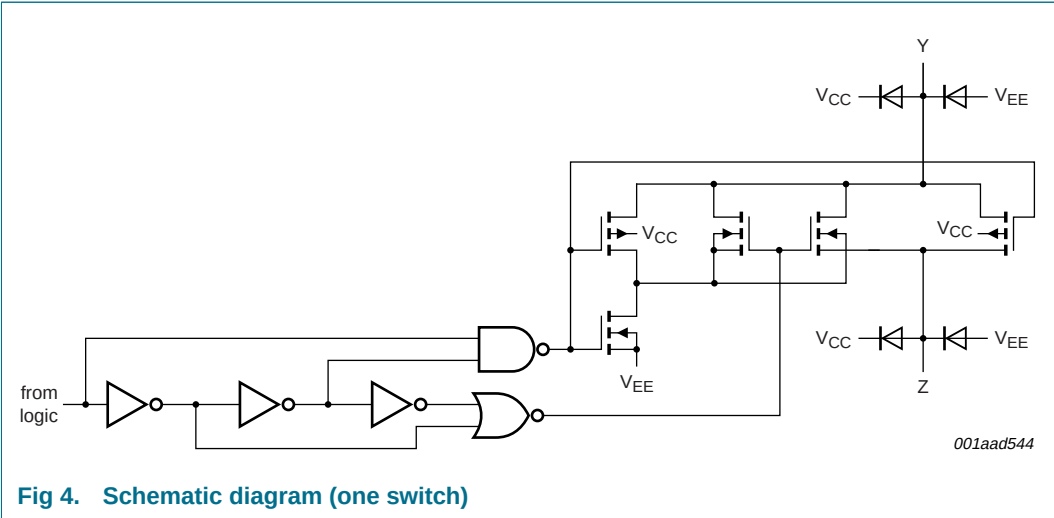


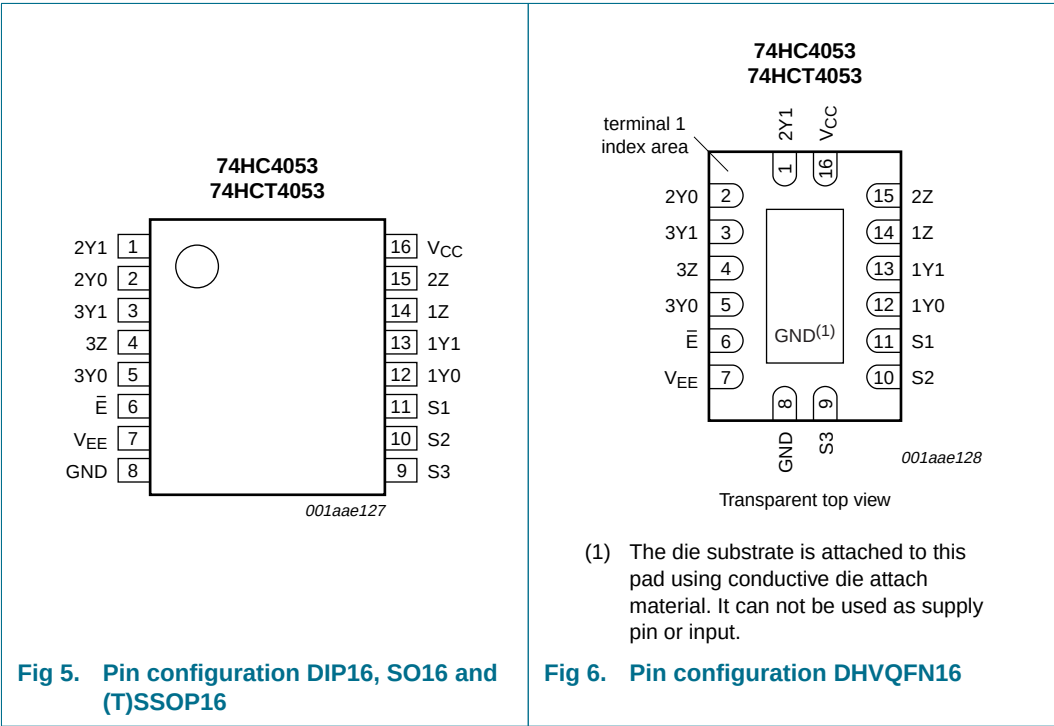
Fig 2. Logic symbol

Fig 3. IEC logic symbol



7. Pinning information

7.1 Pinning



## 7.2 Pin description

Table 3: Pin description

| Symbol    | Pin | Description                  |
|-----------|-----|------------------------------|
| 2Y1       | 1   | 2 independent input/output 1 |
| 2Y0       | 2   | 2 independent input/output 0 |
| 3Y1       | 3   | 3 independent input/output 1 |
| 3Z        | 4   | 3 common input/output        |
| 3Y0       | 5   | 3 independent input/output 0 |
| $\bar{E}$ | 6   | enable input (active LOW)    |
| $V_{EE}$  | 7   | negative supply voltage      |
| GND       | 8   | ground (0 V)                 |
| S3        | 9   | select input 3               |
| S2        | 10  | select input 2               |
| S1        | 11  | select input 1               |
| 1Y0       | 12  | 1 independent input/output 0 |
| 1Y1       | 13  | 1 independent input/output 1 |
| 1Z        | 14  | 1 common input/output        |
| 2Z        | 15  | 2 common input/output        |
| $V_{CC}$  | 16  | supply voltage               |

## 8. Functional description

### 8.1 Function table

Table 4: Function table <sup>[1]</sup>

| Control   |    | Channel on |
|-----------|----|------------|
| $\bar{E}$ | Sn |            |
| L         | L  | nY0 to nZ  |
|           | H  | nY1 to nZ  |
| H         | X  | none       |

[1] H = HIGH voltage level;  
L = LOW voltage level;  
X = don't care.

## 9. Limiting values

Table 5: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to  $V_{EE} = GND$  (ground = 0 V). <sup>[1]</sup>

| Symbol   | Parameter               | Conditions                                             | Min  | Max   | Unit |
|----------|-------------------------|--------------------------------------------------------|------|-------|------|
| $V_{CC}$ | supply voltage          |                                                        | -0.5 | +11.0 | V    |
| $I_{IK}$ | input clamping current  | $V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$ | -    | ±20   | mA   |
| $I_{SK}$ | switch clamping current | $V_S < -0.5\text{ V}$ or $V_S > V_{CC} + 0.5\text{ V}$ | -    | ±20   | mA   |

**Table 5: Limiting values ...continued**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to  $V_{EE} = GND$  (ground = 0 V). [\[1\]](#)

| Symbol    | Parameter                    | Conditions                                    | Min                   | Max      | Unit |
|-----------|------------------------------|-----------------------------------------------|-----------------------|----------|------|
| $I_S$     | switch current               | $-0.5\text{ V} < V_S < V_{CC} + 0.5\text{ V}$ | -                     | $\pm 25$ | mA   |
| $I_{EE}$  | negative supply current      |                                               | -                     | -20      | mA   |
| $I_{CC}$  | quiescent supply current     |                                               | -                     | 50       | mA   |
| $I_{GND}$ | ground current               |                                               | -                     | -50      | mA   |
| $T_{stg}$ | storage temperature          |                                               | -65                   | +150     | °C   |
| $P_{tot}$ | total power dissipation      | $T_{amb} = -40\text{ °C to } +125\text{ °C}$  |                       |          |      |
|           | DIP16 package                |                                               | <a href="#">[2]</a> - | 750      | mW   |
|           | SO16 package                 |                                               | <a href="#">[3]</a> - | 500      | mW   |
|           | SSOP16 package               |                                               | <a href="#">[4]</a> - | 500      | mW   |
|           | TSSOP16 package              |                                               | <a href="#">[4]</a> - | 500      | mW   |
|           | DHVQFN16 package             |                                               | <a href="#">[5]</a> - | 500      | mW   |
| $P_S$     | power dissipation per switch |                                               | -                     | 100      | mW   |

[1] To avoid drawing  $V_{CC}$  current out of terminals nZ, when switch current flows in terminals nYn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminals nZ, no  $V_{CC}$  current will flow out of terminals nYn. In this case there is no limit for the voltage drop across the switch, but the voltages at nYn and nZ may not exceed  $V_{CC}$  or  $V_{EE}$ .

[2] For DIP16 package:  $P_{tot}$  derates linearly with 12 mW/K above 70 °C.

[3] For SO16 package:  $P_{tot}$  derates linearly with 8 mW/K above 70 °C.

[4] For SSOP16 and TSSOP16 packages:  $P_{tot}$  derates linearly with 5.5 mW/K above 60 °C.

[5] For DHVQFN16 packages:  $P_{tot}$  derates linearly with 4.5 mW/K above 60 °C.

## 10. Recommended operating conditions

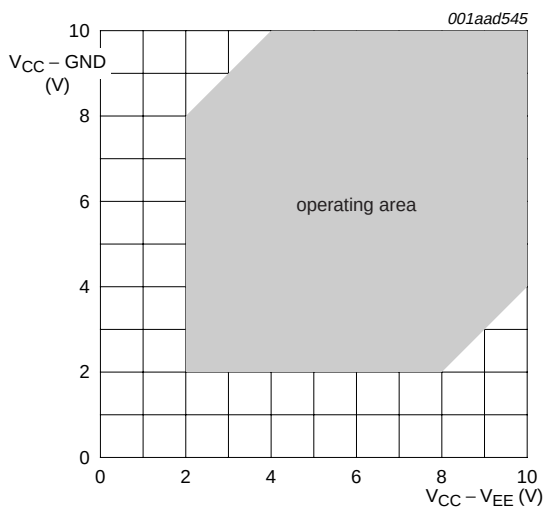
**Table 6: Recommended operating conditions**

| Symbol           | Parameter                 | Conditions                   | Min      | Typ | Max      | Unit |
|------------------|---------------------------|------------------------------|----------|-----|----------|------|
| <b>74HC4053</b>  |                           |                              |          |     |          |      |
| $\Delta V_{CC}$  | supply voltage difference | see <a href="#">Figure 7</a> |          |     |          |      |
|                  | $V_{CC} - GND$            |                              | 2.0      | 5.0 | 10.0     | V    |
|                  | $V_{CC} - V_{EE}$         |                              | 2.0      | 5.0 | 10.0     | V    |
| $V_I$            | input voltage             |                              | GND      | -   | $V_{CC}$ | V    |
| $V_S$            | switch voltage            |                              | $V_{EE}$ | -   | $V_{CC}$ | V    |
| $T_{amb}$        | ambient temperature       |                              | -40      | +25 | +125     | °C   |
| $t_r, t_f$       | input rise and fall times | $V_{CC} = 2.0\text{ V}$      | -        | 6.0 | 1000     | ns   |
|                  |                           | $V_{CC} = 4.5\text{ V}$      | -        | 6.0 | 500      | ns   |
|                  |                           | $V_{CC} = 6.0\text{ V}$      | -        | 6.0 | 400      | ns   |
|                  |                           | $V_{CC} = 10.0\text{ V}$     | -        | 6.0 | 250      | ns   |
| <b>74HCT4053</b> |                           |                              |          |     |          |      |
| $\Delta V_{CC}$  | supply voltage difference | see <a href="#">Figure 7</a> |          |     |          |      |
|                  | $V_{CC} - GND$            |                              | 4.5      | 5.0 | 5.5      | V    |
|                  | $V_{CC} - V_{EE}$         |                              | 2.0      | 5.0 | 10.0     | V    |

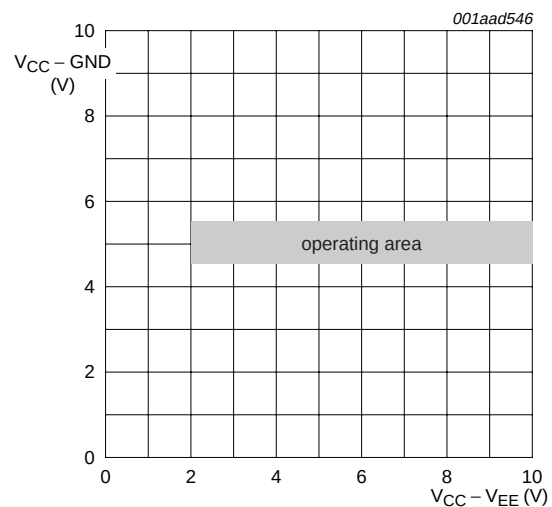


Table 6: Recommended operating conditions ...continued

| Symbol     | Parameter                 | Conditions              | Min      | Typ | Max      | Unit |
|------------|---------------------------|-------------------------|----------|-----|----------|------|
| $V_I$      | input voltage             |                         | GND      | -   | $V_{CC}$ | V    |
| $V_S$      | switch voltage            |                         | $V_{EE}$ | -   | $V_{CC}$ | V    |
| $T_{amb}$  | ambient temperature       |                         | -40      | +25 | +125     | °C   |
| $t_r, t_f$ | input rise and fall times | $V_{CC} = 4.5\text{ V}$ | -        | 6.0 | 500      | ns   |



a. Type 74HC4053



b. Type 74HCT4053

Fig 7. Guaranteed operating area as a function of the supply voltages

## 11. Static characteristics

Table 7:  $R_{ON}$  resistance per switch 74HC4053 and 74HCT4053

For test circuit see [Figure 8](#).

$V_{IS}$  is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

$V_{OS}$  is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

74HC4053 supply voltages:  $V_{CC} - GND$  or  $V_{CC} - V_{EE} = 2.0\text{ V}, 4.5\text{ V}, 6.0\text{ V}$  and  $9.0\text{ V}$ .

74HCT4053 supply voltages:  $V_{CC} - GND = 4.5\text{ V}$  or  $5.5\text{ V}$ ;  $V_{CC} - V_{EE} = 2.0\text{ V}, 4.5\text{ V}, 6.0\text{ V}$  and  $9.0\text{ V}$ .

| Symbol                   | Parameter            | Conditions                                                                           | Min                 | Typ | Max | Unit     |
|--------------------------|----------------------|--------------------------------------------------------------------------------------|---------------------|-----|-----|----------|
| $T_{amb} = 25\text{ °C}$ |                      |                                                                                      |                     |     |     |          |
| $R_{ON(peak)}$           | ON resistance (peak) | $V_{IS} = V_{CC}$ to $V_{EE}$ ; $V_I = V_{IH}$ or $V_{IL}$                           |                     |     |     |          |
|                          |                      | $V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_S = 100\text{ }\mu\text{A}$     | <a href="#">(1)</a> | -   | -   | $\Omega$ |
|                          |                      | $V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_S = 1000\text{ }\mu\text{A}$    | -                   | 100 | 180 | $\Omega$ |
|                          |                      | $V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_S = 1000\text{ }\mu\text{A}$    | -                   | 90  | 160 | $\Omega$ |
|                          |                      | $V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$ ; $I_S = 1000\text{ }\mu\text{A}$ | -                   | 70  | 130 | $\Omega$ |

Table 7:  $R_{ON}$  resistance per switch 74HC4053 and 74HCT4053 ...continued

For test circuit see Figure 8.

 $V_{IS}$  is the input voltage at a nYn or nZ terminal, whichever is assigned as an input. $V_{OS}$  is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.74HC4053 supply voltages:  $V_{CC} - GND$  or  $V_{CC} - V_{EE} = 2.0\text{ V}$ ,  $4.5\text{ V}$ ,  $6.0\text{ V}$  and  $9.0\text{ V}$ .74HCT4053 supply voltages:  $V_{CC} - GND = 4.5\text{ V}$  or  $5.5\text{ V}$ ;  $V_{CC} - V_{EE} = 2.0\text{ V}$ ,  $4.5\text{ V}$ ,  $6.0\text{ V}$  and  $9.0\text{ V}$ .

| Symbol                               | Parameter                               | Conditions                                                                                                 | Min | Typ | Max | Unit |   |
|--------------------------------------|-----------------------------------------|------------------------------------------------------------------------------------------------------------|-----|-----|-----|------|---|
| R <sub>ON(rail)</sub>                | ON resistance (rail)                    | V <sub>IS</sub> = V <sub>EE</sub> ; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                    |     |     |     |      |   |
|                                      |                                         | V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V; I <sub>S</sub> = 100 μA                                    | [1] | -   | 150 | -    | Ω |
|                                      |                                         | V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V; I <sub>S</sub> = 1000 μA                                   | -   | 80  | 140 | Ω    |   |
|                                      |                                         | V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V; I <sub>S</sub> = 1000 μA                                   | -   | 70  | 120 | Ω    |   |
|                                      |                                         | V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V; I <sub>S</sub> = 1000 μA                                | -   | 60  | 105 | Ω    |   |
|                                      |                                         | V <sub>IS</sub> = V <sub>CC</sub> ; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                    |     |     |     |      |   |
|                                      |                                         | V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V; I <sub>S</sub> = 100 μA                                    | [1] | -   | 150 | -    | Ω |
|                                      |                                         | V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V; I <sub>S</sub> = 1000 μA                                   | -   | 90  | 160 | Ω    |   |
|                                      |                                         | V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V; I <sub>S</sub> = 1000 μA                                   | -   | 80  | 140 | Ω    |   |
|                                      |                                         | V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V; I <sub>S</sub> = 1000 μA                                | -   | 65  | 120 | Ω    |   |
| ΔR <sub>ON</sub>                     | ON resistance mismatch between channels | V <sub>IS</sub> = V <sub>CC</sub> to V <sub>EE</sub> ; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> |     |     |     |      |   |
|                                      |                                         | V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V                                                             | [1] | -   | -   | -    | Ω |
|                                      |                                         | V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V                                                             | -   | 9   | -   | Ω    |   |
|                                      |                                         | V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V                                                             | -   | 8   | -   | Ω    |   |
|                                      |                                         | V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V                                                          | -   | 6   | -   | Ω    |   |
| T <sub>amb</sub> = -40 °C to +85 °C  |                                         |                                                                                                            |     |     |     |      |   |
| R <sub>ON(peak)</sub>                | ON resistance (peak)                    | V <sub>IS</sub> = V <sub>CC</sub> to V <sub>EE</sub> ; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> |     |     |     |      |   |
|                                      |                                         | V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V; I <sub>S</sub> = 100 μA                                    | [1] | -   | -   | -    | Ω |
|                                      |                                         | V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V; I <sub>S</sub> = 1000 μA                                   | -   | -   | 225 | Ω    |   |
|                                      |                                         | V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V; I <sub>S</sub> = 1000 μA                                   | -   | -   | 200 | Ω    |   |
|                                      |                                         | V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V; I <sub>S</sub> = 1000 μA                                | -   | -   | 165 | Ω    |   |
| R <sub>ON(rail)</sub>                | ON resistance (rail)                    | V <sub>IS</sub> = V <sub>EE</sub> ; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                    |     |     |     |      |   |
|                                      |                                         | V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V; I <sub>S</sub> = 100 μA                                    | [1] | -   | -   | -    | Ω |
|                                      |                                         | V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V; I <sub>S</sub> = 1000 μA                                   | -   | -   | 175 | Ω    |   |
|                                      |                                         | V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V; I <sub>S</sub> = 1000 μA                                   | -   | -   | 150 | Ω    |   |
|                                      |                                         | V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V; I <sub>S</sub> = 1000 μA                                | -   | -   | 130 | Ω    |   |
|                                      |                                         | V <sub>IS</sub> = V <sub>CC</sub> ; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                    |     |     |     |      |   |
|                                      |                                         | V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V; I <sub>S</sub> = 100 μA                                    | [1] | -   | -   | -    | Ω |
|                                      |                                         | V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V; I <sub>S</sub> = 1000 μA                                   | -   | -   | 200 | Ω    |   |
|                                      |                                         | V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V; I <sub>S</sub> = 1000 μA                                   | -   | -   | 175 | Ω    |   |
|                                      |                                         | V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V; I <sub>S</sub> = 1000 μA                                | -   | -   | 150 | Ω    |   |
| T <sub>amb</sub> = -40 °C to +125 °C |                                         |                                                                                                            |     |     |     |      |   |
| R <sub>ON(peak)</sub>                | ON resistance (peak)                    | V <sub>IS</sub> = V <sub>CC</sub> to V <sub>EE</sub> ; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> |     |     |     |      |   |
|                                      |                                         | V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V; I <sub>S</sub> = 100 μA                                    | [1] | -   | -   | -    | Ω |
|                                      |                                         | V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V; I <sub>S</sub> = 1000 μA                                   | -   | -   | 270 | Ω    |   |
|                                      |                                         | V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V; I <sub>S</sub> = 1000 μA                                   | -   | -   | 240 | Ω    |   |
|                                      |                                         | V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V; I <sub>S</sub> = 1000 μA                                | -   | -   | 195 | Ω    |   |

Table 7:  $R_{ON}$  resistance per switch 74HC4053 and 74HCT4053 ...continued

For test circuit see Figure 8.

$V_{IS}$  is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

$V_{OS}$  is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

74HC4053 supply voltages:  $V_{CC} - GND$  or  $V_{CC} - V_{EE} = 2.0\text{ V}$ ,  $4.5\text{ V}$ ,  $6.0\text{ V}$  and  $9.0\text{ V}$ .

74HCT4053 supply voltages:  $V_{CC} - GND = 4.5\text{ V}$  or  $5.5\text{ V}$ ;  $V_{CC} - V_{EE} = 2.0\text{ V}$ ,  $4.5\text{ V}$ ,  $6.0\text{ V}$  and  $9.0\text{ V}$ .

| Symbol         | Parameter            | Conditions                                                                           | Min | Typ | Max | Unit     |
|----------------|----------------------|--------------------------------------------------------------------------------------|-----|-----|-----|----------|
| $R_{ON(rail)}$ | ON resistance (rail) | $V_{IS} = V_{EE}$ ; $V_I = V_{IH}$ or $V_{IL}$                                       |     |     |     |          |
|                |                      | $V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_S = 100\text{ }\mu\text{A}$     | [1] | -   | -   | $\Omega$ |
|                |                      | $V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_S = 1000\text{ }\mu\text{A}$    | -   | -   | 210 | $\Omega$ |
|                |                      | $V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_S = 1000\text{ }\mu\text{A}$    | -   | -   | 180 | $\Omega$ |
|                |                      | $V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$ ; $I_S = 1000\text{ }\mu\text{A}$ | -   | -   | 160 | $\Omega$ |
|                |                      | $V_{IS} = V_{CC}$ ; $V_I = V_{IH}$ or $V_{IL}$                                       |     |     |     |          |
|                |                      | $V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_S = 100\text{ }\mu\text{A}$     | [1] | -   | -   | $\Omega$ |
|                |                      | $V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_S = 1000\text{ }\mu\text{A}$    | -   | -   | 240 | $\Omega$ |
|                |                      | $V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_S = 1000\text{ }\mu\text{A}$    | -   | -   | 210 | $\Omega$ |
|                |                      | $V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$ ; $I_S = 1000\text{ }\mu\text{A}$ | -   | -   | 180 | $\Omega$ |

[1] At supply voltages ( $V_{CC} - V_{EE}$ ) approaching  $2.0\text{ V}$  the analog switch ON resistance becomes extremely non-linear. Therefore, it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.

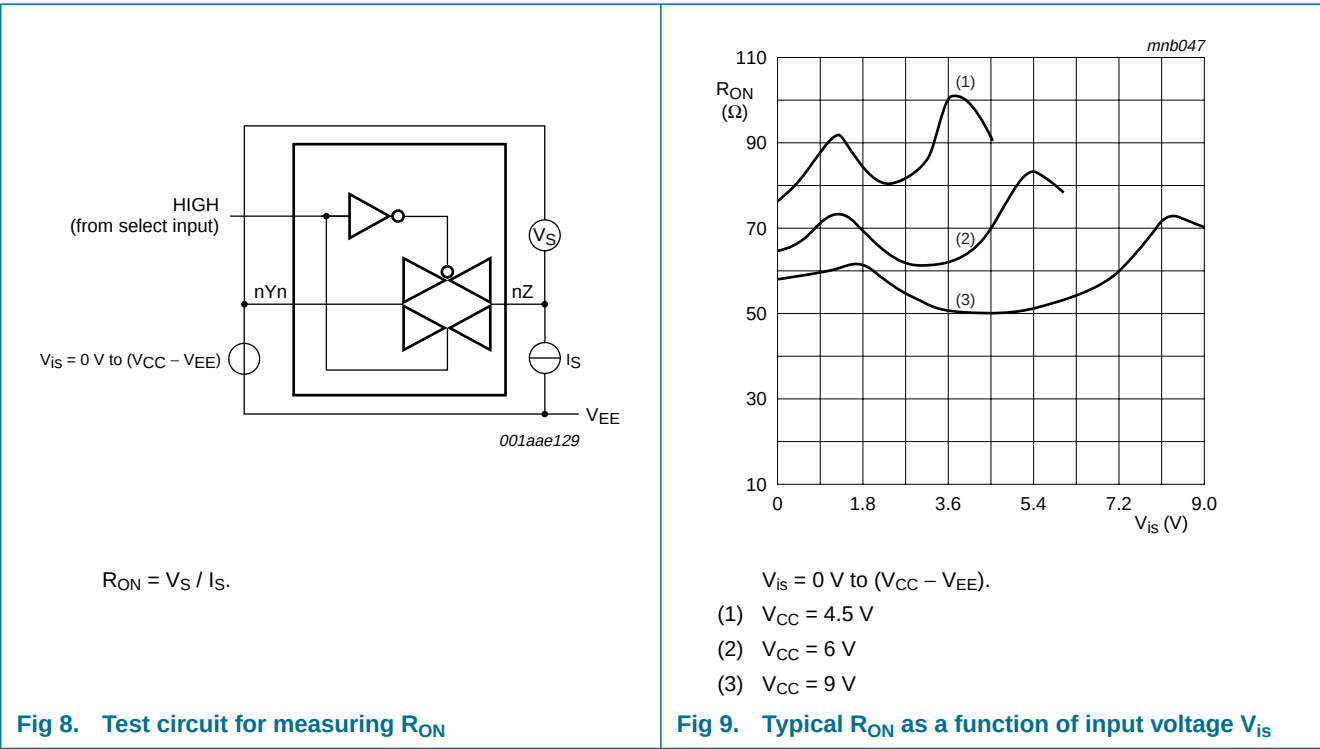


Fig 8. Test circuit for measuring  $R_{ON}$

Fig 9. Typical  $R_{ON}$  as a function of input voltage  $V_{IS}$

**Table 8: Static characteristics 74HC4053**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

$V_{IS}$  is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

$V_{OS}$  is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

| Symbol                              | Parameter                 | Conditions                                                                                                                                                                                   | Min  | Typ | Max  | Unit |
|-------------------------------------|---------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|-----|------|------|
| T <sub>amb</sub> = 25 °C            |                           |                                                                                                                                                                                              |      |     |      |      |
| V <sub>IH</sub>                     | HIGH-state input voltage  | V <sub>CC</sub> = 2.0 V                                                                                                                                                                      | 1.5  | 1.2 | -    | V    |
|                                     |                           | V <sub>CC</sub> = 4.5 V                                                                                                                                                                      | 3.15 | 2.4 | -    | V    |
|                                     |                           | V <sub>CC</sub> = 6.0 V                                                                                                                                                                      | 4.2  | 3.2 | -    | V    |
|                                     |                           | V <sub>CC</sub> = 9.0 V                                                                                                                                                                      | 6.3  | 4.7 | -    | V    |
| V <sub>IL</sub>                     | LOW-state input voltage   | V <sub>CC</sub> = 2.0 V                                                                                                                                                                      | -    | 0.8 | 0.5  | V    |
|                                     |                           | V <sub>CC</sub> = 4.5 V                                                                                                                                                                      | -    | 2.1 | 1.35 | V    |
|                                     |                           | V <sub>CC</sub> = 6.0 V                                                                                                                                                                      | -    | 2.8 | 1.8  | V    |
|                                     |                           | V <sub>CC</sub> = 9.0 V                                                                                                                                                                      | -    | 4.3 | 2.7  | V    |
| I <sub>LI</sub>                     | input leakage current     | V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>EE</sub> = 0 V                                                                                                                               |      |     |      |      |
|                                     |                           | V <sub>CC</sub> = 6.0 V                                                                                                                                                                      | -    | -   | ±0.1 | µA   |
|                                     |                           | V <sub>CC</sub> = 10.0 V                                                                                                                                                                     | -    | -   | ±0.2 | µA   |
| I <sub>S(OFF)</sub>                 | OFF-state leakage current | V <sub>CC</sub> = 10.0 V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>EE</sub> = 0 V;  V <sub>S</sub>   = V <sub>CC</sub> – V <sub>EE</sub> ; see <a href="#">Figure 10</a> |      |     |      |      |
|                                     |                           | per channel                                                                                                                                                                                  | -    | -   | ±0.1 | µA   |
|                                     |                           | all channels                                                                                                                                                                                 | -    | -   | ±0.1 | µA   |
| I <sub>S(ON)</sub>                  | ON-state leakage current  | V <sub>CC</sub> = 10.0 V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>EE</sub> = 0 V;  V <sub>S</sub>   = V <sub>CC</sub> – V <sub>EE</sub> ; see <a href="#">Figure 11</a> | -    | -   | ±0.1 | µA   |
| I <sub>CC</sub>                     | quiescent supply current  | V <sub>is</sub> = V <sub>EE</sub> or V <sub>CC</sub> ; V <sub>os</sub> = V <sub>CC</sub> or V <sub>EE</sub> ; V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>EE</sub> = 0 V                 |      |     |      |      |
|                                     |                           | V <sub>CC</sub> = 6.0 V                                                                                                                                                                      | -    | -   | 8.0  | µA   |
|                                     |                           | V <sub>CC</sub> = 10.0 V                                                                                                                                                                     | -    | -   | 16.0 | µA   |
| C <sub>i</sub>                      | input capacitance         |                                                                                                                                                                                              | -    | 3.5 | -    | pF   |
| C <sub>S</sub>                      | switch capacitance        |                                                                                                                                                                                              |      |     |      |      |
|                                     | independent I/O (nYn)     |                                                                                                                                                                                              | -    | 5   | -    | pF   |
|                                     | common I/O (nZ)           |                                                                                                                                                                                              | -    | 8   | -    | pF   |
| T <sub>amb</sub> = –40 °C to +85 °C |                           |                                                                                                                                                                                              |      |     |      |      |
| V <sub>IH</sub>                     | HIGH-state input voltage  | V <sub>CC</sub> = 2.0 V                                                                                                                                                                      | 1.5  | -   | -    | V    |
|                                     |                           | V <sub>CC</sub> = 4.5 V                                                                                                                                                                      | 3.15 | -   | -    | V    |
|                                     |                           | V <sub>CC</sub> = 6.0 V                                                                                                                                                                      | 4.2  | -   | -    | V    |
|                                     |                           | V <sub>CC</sub> = 9.0 V                                                                                                                                                                      | 6.3  | -   | -    | V    |
| V <sub>IL</sub>                     | LOW-state input voltage   | V <sub>CC</sub> = 2.0 V                                                                                                                                                                      | -    | -   | 0.5  | V    |
|                                     |                           | V <sub>CC</sub> = 4.5 V                                                                                                                                                                      | -    | -   | 1.35 | V    |
|                                     |                           | V <sub>CC</sub> = 6.0 V                                                                                                                                                                      | -    | -   | 1.8  | V    |
|                                     |                           | V <sub>CC</sub> = 9.0 V                                                                                                                                                                      | -    | -   | 2.7  | V    |
| I <sub>LI</sub>                     | input leakage current     | V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>EE</sub> = 0 V                                                                                                                               |      |     |      |      |
|                                     |                           | V <sub>CC</sub> = 6.0 V                                                                                                                                                                      | -    | -   | ±1.0 | µA   |
|                                     |                           | V <sub>CC</sub> = 10.0 V                                                                                                                                                                     | -    | -   | ±2.0 | µA   |

**Table 8:** Static characteristics 74HC4053 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

 $V_{IS}$  is the input voltage at a nYn or nZ terminal, whichever is assigned as an input. $V_{OS}$  is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

| Symbol                               | Parameter                 | Conditions                                                                                                                                                                                   | Min  | Typ | Max   | Unit |
|--------------------------------------|---------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|-----|-------|------|
| I <sub>S(OFF)</sub>                  | OFF-state leakage current | V <sub>CC</sub> = 10.0 V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>EE</sub> = 0 V;  V <sub>S</sub>   = V <sub>CC</sub> – V <sub>EE</sub> ; see <a href="#">Figure 10</a> |      |     |       |      |
|                                      |                           | per channel                                                                                                                                                                                  | -    | -   | ±1.0  | μA   |
|                                      |                           | all channels                                                                                                                                                                                 | -    | -   | ±1.0  | μA   |
| I <sub>S(ON)</sub>                   | ON-state leakage current  | V <sub>CC</sub> = 10.0 V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>EE</sub> = 0 V;  V <sub>S</sub>   = V <sub>CC</sub> – V <sub>EE</sub> ; see <a href="#">Figure 11</a> | -    | -   | ±1.0  | μA   |
| I <sub>CC</sub>                      | quiescent supply current  | V <sub>is</sub> = V <sub>EE</sub> or V <sub>CC</sub> ; V <sub>os</sub> = V <sub>CC</sub> or V <sub>EE</sub> ; V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>EE</sub> = 0 V                 |      |     |       |      |
|                                      |                           | V <sub>CC</sub> = 6.0 V                                                                                                                                                                      | -    | -   | 80.0  | μA   |
|                                      |                           | V <sub>CC</sub> = 10.0 V                                                                                                                                                                     | -    | -   | 160.0 | μA   |
| T <sub>amb</sub> = –40 °C to +125 °C |                           |                                                                                                                                                                                              |      |     |       |      |
| V <sub>IH</sub>                      | HIGH-state input voltage  | V <sub>CC</sub> = 2.0 V                                                                                                                                                                      | 1.5  | -   | -     | V    |
|                                      |                           | V <sub>CC</sub> = 4.5 V                                                                                                                                                                      | 3.15 | -   | -     | V    |
|                                      |                           | V <sub>CC</sub> = 6.0 V                                                                                                                                                                      | 4.2  | -   | -     | V    |
|                                      |                           | V <sub>CC</sub> = 9.0 V                                                                                                                                                                      | 6.3  | -   | -     | V    |
| V <sub>IL</sub>                      | LOW-state input voltage   | V <sub>CC</sub> = 2.0 V                                                                                                                                                                      | -    | -   | 0.5   | V    |
|                                      |                           | V <sub>CC</sub> = 4.5 V                                                                                                                                                                      | -    | -   | 1.35  | V    |
|                                      |                           | V <sub>CC</sub> = 6.0 V                                                                                                                                                                      | -    | -   | 1.8   | V    |
|                                      |                           | V <sub>CC</sub> = 9.0 V                                                                                                                                                                      | -    | -   | 2.7   | V    |
| I <sub>LI</sub>                      | input leakage current     | V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>EE</sub> = 0 V                                                                                                                               |      |     |       |      |
|                                      |                           | V <sub>CC</sub> = 6.0 V                                                                                                                                                                      | -    | -   | ±1.0  | μA   |
|                                      |                           | V <sub>CC</sub> = 10.0 V                                                                                                                                                                     | -    | -   | ±2.0  | μA   |
| I <sub>S(OFF)</sub>                  | OFF-state leakage current | V <sub>CC</sub> = 10.0 V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>EE</sub> = 0 V;  V <sub>S</sub>   = V <sub>CC</sub> – V <sub>EE</sub> ; see <a href="#">Figure 10</a> |      |     |       |      |
|                                      |                           | per channel                                                                                                                                                                                  | -    | -   | ±1.0  | μA   |
|                                      |                           | all channels                                                                                                                                                                                 | -    | -   | ±1.0  | μA   |
| I <sub>S(ON)</sub>                   | ON-state leakage current  | V <sub>CC</sub> = 10.0 V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>EE</sub> = 0 V;  V <sub>S</sub>   = V <sub>CC</sub> – V <sub>EE</sub> ; see <a href="#">Figure 11</a> | -    | -   | ±1.0  | μA   |
| I <sub>CC</sub>                      | quiescent supply current  | V <sub>is</sub> = V <sub>EE</sub> or V <sub>CC</sub> ; V <sub>os</sub> = V <sub>CC</sub> or V <sub>EE</sub> ; V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>EE</sub> = 0 V                 |      |     |       |      |
|                                      |                           | V <sub>CC</sub> = 6.0 V                                                                                                                                                                      | -    | -   | 160.0 | μA   |
|                                      |                           | V <sub>CC</sub> = 10.0 V                                                                                                                                                                     | -    | -   | 320.0 | μA   |

**Table 9:** Static characteristics 74HCT4053

Voltages are referenced to GND (ground = 0 V).

 $V_{IS}$  is the input voltage at a nYn or nZ terminal, whichever is assigned as an input. $V_{OS}$  is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

| Symbol                                                   | Parameter                | Conditions                                | Min | Typ | Max | Unit          |
|----------------------------------------------------------|--------------------------|-------------------------------------------|-----|-----|-----|---------------|
| <b><math>T_{amb} = 25\text{ }^{\circ}\text{C}</math></b> |                          |                                           |     |     |     |               |
| $V_{IH}$                                                 | HIGH-state input voltage | $V_{CC} = 4.5\text{ V}$ to $5.5\text{ V}$ | 2.0 | 1.6 | -   | $\mu\text{A}$ |
| $V_{IL}$                                                 | LOW-state input voltage  | $V_{CC} = 4.5\text{ V}$ to $5.5\text{ V}$ | -   | 1.2 | 0.8 | $\mu\text{A}$ |

**Table 9: Static characteristics 74HCT4053 ...continued**

Voltages are referenced to GND (ground = 0 V).

$V_{IS}$  is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

$V_{OS}$  is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

| Symbol                               | Parameter                           | Conditions                                                                                                                                                                                   | Min | Typ | Max   | Unit |
|--------------------------------------|-------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----|-----|-------|------|
| I <sub>LI</sub>                      | input leakage current               | V <sub>CC</sub> = 5.5 V; V <sub>EE</sub> = 0 V; V <sub>I</sub> = V <sub>CC</sub> or GND                                                                                                      | -   | -   | ±0.1  | μA   |
| I <sub>S(OFF)</sub>                  | OFF-state leakage current           | V <sub>CC</sub> = 10.0 V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>EE</sub> = 0 V;  V <sub>S</sub>   = V <sub>CC</sub> – V <sub>EE</sub> ; see <a href="#">Figure 10</a> |     |     |       |      |
|                                      |                                     | per channel                                                                                                                                                                                  | -   | -   | ±0.1  | μA   |
|                                      |                                     | all channels                                                                                                                                                                                 | -   | -   | ±0.1  | μA   |
| I <sub>S(ON)</sub>                   | ON-state leakage current            | V <sub>CC</sub> = 10.0 V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>EE</sub> = 0 V;  V <sub>S</sub>   = V <sub>CC</sub> – V <sub>EE</sub> ; see <a href="#">Figure 11</a> | -   | -   | ±0.1  | μA   |
| I <sub>CC</sub>                      | quiescent supply current            | V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>is</sub> = V <sub>EE</sub> or V <sub>CC</sub> ; V <sub>os</sub> = V <sub>CC</sub> or V <sub>EE</sub>                                         |     |     |       |      |
|                                      |                                     | V <sub>CC</sub> = 5.5 V; V <sub>EE</sub> = 0 V                                                                                                                                               | -   | -   | 8.0   | μA   |
|                                      |                                     | V <sub>CC</sub> = 5.0 V; V <sub>EE</sub> = –5.0 V                                                                                                                                            | -   | -   | 16.0  | μA   |
| ΔI <sub>CC</sub>                     | additional quiescent supply current | per input pin; V <sub>CC</sub> = 4.5 V to 5.5 V; V <sub>EE</sub> = 0 V; V <sub>I</sub> = V <sub>CC</sub> – 2.1 V; other inputs at V <sub>CC</sub> or GND                                     | -   | 50  | 180   | μA   |
| C <sub>i</sub>                       | input capacitance                   |                                                                                                                                                                                              | -   | 3.5 | -     | pF   |
| C <sub>S</sub>                       | switch capacitance                  |                                                                                                                                                                                              |     |     |       |      |
|                                      | independent I/O (nYn)               |                                                                                                                                                                                              | -   | 5   | -     | pF   |
|                                      | common I/O (nZ)                     |                                                                                                                                                                                              | -   | 8   | -     | pF   |
| T <sub>amb</sub> = –40 °C to +85 °C  |                                     |                                                                                                                                                                                              |     |     |       |      |
| V <sub>IH</sub>                      | HIGH-state input voltage            | V <sub>CC</sub> = 4.5 V to 5.5 V                                                                                                                                                             | 2.0 | -   | -     | μA   |
| V <sub>IL</sub>                      | LOW-state input voltage             | V <sub>CC</sub> = 4.5 V to 5.5 V                                                                                                                                                             | -   | -   | 0.8   | μA   |
| I <sub>LI</sub>                      | input leakage current               | V <sub>CC</sub> = 5.5 V; V <sub>EE</sub> = 0 V; V <sub>I</sub> = V <sub>CC</sub> or GND                                                                                                      | -   | -   | ±1.0  | μA   |
| I <sub>S(OFF)</sub>                  | OFF-state leakage current           | V <sub>CC</sub> = 10.0 V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>EE</sub> = 0 V;  V <sub>S</sub>   = V <sub>CC</sub> – V <sub>EE</sub> ; see <a href="#">Figure 10</a> |     |     |       |      |
|                                      |                                     | per channel                                                                                                                                                                                  | -   | -   | ±1.0  | μA   |
|                                      |                                     | all channels                                                                                                                                                                                 | -   | -   | ±1.0  | μA   |
| I <sub>S(ON)</sub>                   | ON-state leakage current            | V <sub>CC</sub> = 10.0 V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>EE</sub> = 0 V;  V <sub>S</sub>   = V <sub>CC</sub> – V <sub>EE</sub> ; see <a href="#">Figure 11</a> | -   | -   | ±1.0  | μA   |
| I <sub>CC</sub>                      | quiescent supply current            | V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>is</sub> = V <sub>EE</sub> or V <sub>CC</sub> ; V <sub>os</sub> = V <sub>CC</sub> or V <sub>EE</sub>                                         |     |     |       |      |
|                                      |                                     | V <sub>CC</sub> = 5.5 V; V <sub>EE</sub> = 0 V                                                                                                                                               | -   | -   | 80.0  | μA   |
|                                      |                                     | V <sub>CC</sub> = 5.0 V; V <sub>EE</sub> = –5.0 V                                                                                                                                            | -   | -   | 160.0 | μA   |
| ΔI <sub>CC</sub>                     | additional quiescent supply current | per input pin; V <sub>CC</sub> = 4.5 V to 5.5 V; V <sub>EE</sub> = 0 V; V <sub>I</sub> = V <sub>CC</sub> – 2.1 V; other inputs at V <sub>CC</sub> or GND                                     | -   | -   | 225   | μA   |
| T <sub>amb</sub> = –40 °C to +125 °C |                                     |                                                                                                                                                                                              |     |     |       |      |
| V <sub>IH</sub>                      | HIGH-state input voltage            | V <sub>CC</sub> = 4.5 V to 5.5 V                                                                                                                                                             | 2.0 | -   | -     | μA   |
| V <sub>IL</sub>                      | LOW-state input voltage             | V <sub>CC</sub> = 4.5 V to 5.5 V                                                                                                                                                             | -   | -   | 0.8   | μA   |
| I <sub>LI</sub>                      | input leakage current               | V <sub>CC</sub> = 5.5 V; V <sub>EE</sub> = 0 V; V <sub>I</sub> = V <sub>CC</sub> or GND                                                                                                      | -   | -   | ±1.0  | μA   |

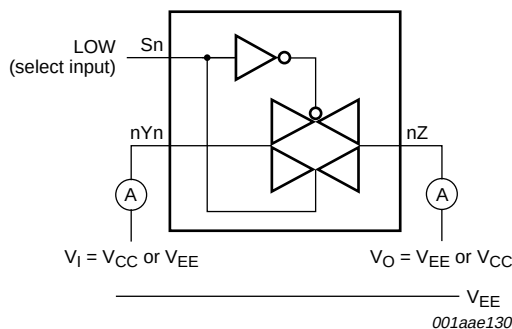
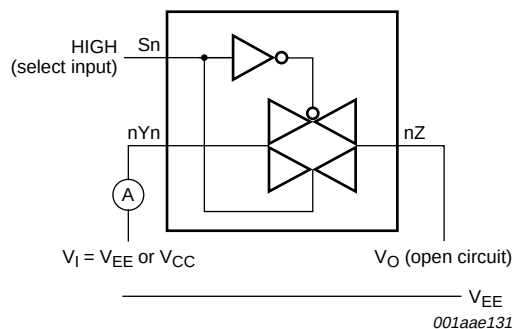
**Table 9:** Static characteristics 74HCT4053 ...continued

Voltages are referenced to GND (ground = 0 V).

$V_{IS}$  is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

$V_{OS}$  is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

| Symbol          | Parameter                           | Conditions                                                                                                                                               | Min | Typ | Max       | Unit          |
|-----------------|-------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------|-----|-----|-----------|---------------|
| $I_{S(OFF)}$    | OFF-state leakage current           | $V_{CC} = 10.0\text{ V}$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $V_{EE} = 0\text{ V}$ ;<br>$ V_S  = V_{CC} - V_{EE}$ ; see <a href="#">Figure 10</a>             |     |     |           |               |
|                 |                                     | per channel                                                                                                                                              | -   | -   | $\pm 1.0$ | $\mu\text{A}$ |
|                 |                                     | all channels                                                                                                                                             | -   | -   | $\pm 1.0$ | $\mu\text{A}$ |
| $I_{S(ON)}$     | ON-state leakage current            | $V_{CC} = 10.0\text{ V}$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $V_{EE} = 0\text{ V}$ ;<br>$ V_S  = V_{CC} - V_{EE}$ ; see <a href="#">Figure 11</a>             | -   | -   | $\pm 1.0$ | $\mu\text{A}$ |
| $I_{CC}$        | quiescent supply current            | $V_I = V_{CC}$ or GND; $V_{IS} = V_{EE}$ or $V_{CC}$ ;<br>$V_{OS} = V_{CC}$ or $V_{EE}$                                                                  |     |     |           |               |
|                 |                                     | $V_{CC} = 5.5\text{ V}$ ; $V_{EE} = 0\text{ V}$                                                                                                          | -   | -   | 160.0     | $\mu\text{A}$ |
|                 |                                     | $V_{CC} = 5.0\text{ V}$ ; $V_{EE} = -5.0\text{ V}$                                                                                                       | -   | -   | 320.0     | $\mu\text{A}$ |
| $\Delta I_{CC}$ | additional quiescent supply current | per input pin; $V_{CC} = 4.5\text{ V}$ to $5.5\text{ V}$ ;<br>$V_{EE} = 0\text{ V}$ ; $V_I = V_{CC} - 2.1\text{ V}$ ; other inputs<br>at $V_{CC}$ or GND | -   | -   | 245       | $\mu\text{A}$ |

**Fig 10.** Test circuit for measuring OFF-state leakage current**Fig 11.** Test circuit for measuring ON-state leakage current

## 12. Dynamic characteristics

**Table 10:** Dynamic characteristics type 74HC4053

Voltages are referenced to GND (ground = 0 V);  $t_r = t_f = 6\text{ ns}$ ;  $C_L = 50\text{ pF}$  unless otherwise specified; for test circuit see [Figure 14](#).

$V_{IS}$  is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

$V_{OS}$  is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

| Symbol                                                   | Parameter                              | Conditions                                                   | Min | Typ | Max | Unit |
|----------------------------------------------------------|----------------------------------------|--------------------------------------------------------------|-----|-----|-----|------|
| <b><math>T_{amb} = 25\text{ }^{\circ}\text{C}</math></b> |                                        |                                                              |     |     |     |      |
| $t_{PHL}$ ,<br>$t_{PLH}$                                 | propagation delay $V_{IS}$ to $V_{OS}$ | $R_L = \infty\text{ }\Omega$ ; see <a href="#">Figure 12</a> |     |     |     |      |
|                                                          |                                        | $V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$              | -   | 15  | 60  | ns   |
|                                                          |                                        | $V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$              | -   | 5   | 12  | ns   |
|                                                          |                                        | $V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$              | -   | 4   | 10  | ns   |
|                                                          |                                        | $V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$           | -   | 4   | 8   | ns   |

**Table 10: Dynamic characteristics type 74HC4053 ...continued**

Voltages are referenced to GND (ground = 0 V);  $t_r = t_f = 6$  ns;  $C_L = 50$  pF unless otherwise specified; for test circuit see Figure 14.

$V_{is}$  is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

$V_{os}$  is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

| Symbol                                                      | Parameter                              | Conditions                                    | Min   | Typ | Max | Unit |
|-------------------------------------------------------------|----------------------------------------|-----------------------------------------------|-------|-----|-----|------|
| $t_{PZH}$ ,<br>$t_{PZL}$                                    | turn-ON time                           | $R_L = 1$ k $\Omega$ ; see Figure 13          |       |     |     |      |
|                                                             | $\bar{E}$ to $V_{os}$                  | $V_{CC} = 2.0$ V; $V_{EE} = 0$ V              | -     | 60  | 220 | ns   |
|                                                             |                                        | $V_{CC} = 4.5$ V; $V_{EE} = 0$ V              | -     | 20  | 44  | ns   |
|                                                             |                                        | $V_{CC} = 6.0$ V; $V_{EE} = 0$ V              | -     | 16  | 37  | ns   |
|                                                             |                                        | $V_{CC} = 4.5$ V; $V_{EE} = -4.5$ V           | -     | 15  | 31  | ns   |
|                                                             |                                        | $V_{CC} = 5$ V; $V_{EE} = 0$ V; $C_L = 15$ pF | -     | 17  | -   | ns   |
|                                                             | Sn to $V_{os}$                         | $V_{CC} = 2.0$ V; $V_{EE} = 0$ V              | -     | 75  | 220 | ns   |
|                                                             |                                        | $V_{CC} = 4.5$ V; $V_{EE} = 0$ V              | -     | 25  | 44  | ns   |
|                                                             |                                        | $V_{CC} = 6.0$ V; $V_{EE} = 0$ V              | -     | 20  | 37  | ns   |
|                                                             |                                        | $V_{CC} = 4.5$ V; $V_{EE} = -4.5$ V           | -     | 15  | 31  | ns   |
|                                                             |                                        | $V_{CC} = 5$ V; $V_{EE} = 0$ V; $C_L = 15$ pF | -     | 21  | -   | ns   |
| $t_{PHZ}$ ,<br>$t_{PLZ}$                                    | turn-OFF time                          | $R_L = 1$ k $\Omega$ ; see Figure 13          |       |     |     |      |
|                                                             | $\bar{E}$ to $V_{os}$                  | $V_{CC} = 2.0$ V; $V_{EE} = 0$ V              | -     | 63  | 210 | ns   |
|                                                             |                                        | $V_{CC} = 4.5$ V; $V_{EE} = 0$ V              | -     | 21  | 42  | ns   |
|                                                             |                                        | $V_{CC} = 6.0$ V; $V_{EE} = 0$ V              | -     | 17  | 36  | ns   |
|                                                             |                                        | $V_{CC} = 4.5$ V; $V_{EE} = -4.5$ V           | -     | 15  | 29  | ns   |
|                                                             |                                        | $V_{CC} = 5$ V; $C_L = 15$ pF                 | -     | 18  | -   | ns   |
|                                                             | Sn to $V_{os}$                         | $V_{CC} = 2.0$ V; $V_{EE} = 0$ V              | -     | 60  | 210 | ns   |
|                                                             |                                        | $V_{CC} = 4.5$ V; $V_{EE} = 0$ V              | -     | 20  | 42  | ns   |
|                                                             |                                        | $V_{CC} = 6.0$ V; $V_{EE} = 0$ V              | -     | 16  | 36  | ns   |
|                                                             |                                        | $V_{CC} = 4.5$ V; $V_{EE} = -4.5$ V           | -     | 15  | 29  | ns   |
|                                                             |                                        | $V_{CC} = 5$ V; $C_L = 15$ pF                 | -     | 17  | -   | ns   |
| $C_{PD}$                                                    | power dissipation capacitance          | per switch; $V_I = \text{GND to } V_{CC}$     | [1] - | 36  | -   | pF   |
| <b><math>T_{amb} = -40</math> °C to <math>+85</math> °C</b> |                                        |                                               |       |     |     |      |
| $t_{PHL}$ ,<br>$t_{PLH}$                                    | propagation delay $V_{is}$ to $V_{os}$ | $R_L = \infty$ $\Omega$ ; see Figure 12       |       |     |     |      |
|                                                             |                                        | $V_{CC} = 2.0$ V; $V_{EE} = 0$ V              | -     | -   | 75  | ns   |
|                                                             |                                        | $V_{CC} = 4.5$ V; $V_{EE} = 0$ V              | -     | -   | 15  | ns   |
|                                                             |                                        | $V_{CC} = 6.0$ V; $V_{EE} = 0$ V              | -     | -   | 13  | ns   |
|                                                             |                                        | $V_{CC} = 4.5$ V; $V_{EE} = -4.5$ V           | -     | -   | 10  | ns   |



**Table 10: Dynamic characteristics type 74HC4053 ...continued**

Voltages are referenced to GND (ground = 0 V);  $t_r = t_f = 6$  ns;  $C_L = 50$  pF unless otherwise specified; for test circuit see Figure 14.

$V_{is}$  is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

$V_{os}$  is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

| Symbol                                                       | Parameter                              | Conditions                              | Min | Typ | Max | Unit |
|--------------------------------------------------------------|----------------------------------------|-----------------------------------------|-----|-----|-----|------|
| $t_{PZH},$<br>$t_{PZL}$                                      | turn-ON time                           | $R_L = 1$ k $\Omega$ ; see Figure 13    |     |     |     |      |
|                                                              | $\bar{E}$ to $V_{os}$                  | $V_{CC} = 2.0$ V; $V_{EE} = 0$ V        | -   | -   | 275 | ns   |
|                                                              |                                        | $V_{CC} = 4.5$ V; $V_{EE} = 0$ V        | -   | -   | 55  | ns   |
|                                                              |                                        | $V_{CC} = 6.0$ V; $V_{EE} = 0$ V        | -   | -   | 47  | ns   |
|                                                              |                                        | $V_{CC} = 4.5$ V; $V_{EE} = -4.5$ V     | -   | -   | 39  | ns   |
|                                                              | Sn to $V_{os}$                         | $V_{CC} = 2.0$ V; $V_{EE} = 0$ V        | -   | -   | 275 | ns   |
|                                                              |                                        | $V_{CC} = 4.5$ V; $V_{EE} = 0$ V        | -   | -   | 55  | ns   |
|                                                              |                                        | $V_{CC} = 6.0$ V; $V_{EE} = 0$ V        | -   | -   | 47  | ns   |
|                                                              |                                        | $V_{CC} = 4.5$ V; $V_{EE} = -4.5$ V     | -   | -   | 39  | ns   |
| $t_{PHZ},$<br>$t_{PLZ}$                                      | turn-OFF time                          | $R_L = 1$ k $\Omega$ ; see Figure 13    |     |     |     |      |
|                                                              | $\bar{E}$ to $V_{os}$                  | $V_{CC} = 2.0$ V; $V_{EE} = 0$ V        | -   | -   | 265 | ns   |
|                                                              |                                        | $V_{CC} = 4.5$ V; $V_{EE} = 0$ V        | -   | -   | 53  | ns   |
|                                                              |                                        | $V_{CC} = 6.0$ V; $V_{EE} = 0$ V        | -   | -   | 45  | ns   |
|                                                              |                                        | $V_{CC} = 4.5$ V; $V_{EE} = -4.5$ V     | -   | -   | 36  | ns   |
|                                                              | Sn to $V_{os}$                         | $V_{CC} = 2.0$ V; $V_{EE} = 0$ V        | -   | -   | 265 | ns   |
|                                                              |                                        | $V_{CC} = 4.5$ V; $V_{EE} = 0$ V        | -   | -   | 53  | ns   |
|                                                              |                                        | $V_{CC} = 6.0$ V; $V_{EE} = 0$ V        | -   | -   | 45  | ns   |
|                                                              |                                        | $V_{CC} = 4.5$ V; $V_{EE} = -4.5$ V     | -   | -   | 36  | ns   |
| <b><math>T_{amb} = -40</math> °C to <math>+125</math> °C</b> |                                        |                                         |     |     |     |      |
| $t_{PHL},$<br>$t_{PLH}$                                      | propagation delay $V_{is}$ to $V_{os}$ | $R_L = \infty$ $\Omega$ ; see Figure 12 |     |     |     |      |
|                                                              |                                        | $V_{CC} = 2.0$ V; $V_{EE} = 0$ V        | -   | -   | 90  | ns   |
|                                                              |                                        | $V_{CC} = 4.5$ V; $V_{EE} = 0$ V        | -   | -   | 18  | ns   |
|                                                              |                                        | $V_{CC} = 6.0$ V; $V_{EE} = 0$ V        | -   | -   | 15  | ns   |
|                                                              |                                        | $V_{CC} = 4.5$ V; $V_{EE} = -4.5$ V     | -   | -   | 12  | ns   |
| $t_{PZH},$<br>$t_{PZL}$                                      | turn-ON time                           | $R_L = 1$ k $\Omega$ ; see Figure 13    |     |     |     |      |
|                                                              | $\bar{E}$ to $V_{os}$                  | $V_{CC} = 2.0$ V; $V_{EE} = 0$ V        | -   | -   | 330 | ns   |
|                                                              |                                        | $V_{CC} = 4.5$ V; $V_{EE} = 0$ V        | -   | -   | 66  | ns   |
|                                                              |                                        | $V_{CC} = 6.0$ V; $V_{EE} = 0$ V        | -   | -   | 56  | ns   |
|                                                              |                                        | $V_{CC} = 4.5$ V; $V_{EE} = -4.5$ V     | -   | -   | 47  | ns   |
|                                                              | Sn to $V_{os}$                         | $V_{CC} = 2.0$ V; $V_{EE} = 0$ V        | -   | -   | 330 | ns   |
|                                                              |                                        | $V_{CC} = 4.5$ V; $V_{EE} = 0$ V        | -   | -   | 66  | ns   |
|                                                              |                                        | $V_{CC} = 6.0$ V; $V_{EE} = 0$ V        | -   | -   | 56  | ns   |
|                                                              |                                        | $V_{CC} = 4.5$ V; $V_{EE} = -4.5$ V     | -   | -   | 47  | ns   |

**Table 10: Dynamic characteristics type 74HC4053 ...continued**

Voltages are referenced to GND (ground = 0 V);  $t_r = t_f = 6$  ns;  $C_L = 50$  pF unless otherwise specified; for test circuit see Figure 14.

$V_{is}$  is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

$V_{os}$  is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

| Symbol                   | Parameter             | Conditions                           | Min | Typ | Max | Unit |
|--------------------------|-----------------------|--------------------------------------|-----|-----|-----|------|
| $t_{PHZ}$ ,<br>$t_{PLZ}$ | turn-OFF time         | $R_L = 1$ k $\Omega$ ; see Figure 13 |     |     |     |      |
|                          | $\bar{E}$ to $V_{os}$ | $V_{CC} = 2.0$ V; $V_{EE} = 0$ V     | -   | -   | 315 | ns   |
|                          |                       | $V_{CC} = 4.5$ V; $V_{EE} = 0$ V     | -   | -   | 63  | ns   |
|                          |                       | $V_{CC} = 6.0$ V; $V_{EE} = 0$ V     | -   | -   | 54  | ns   |
|                          |                       | $V_{CC} = 4.5$ V; $V_{EE} = -4.5$ V  | -   | -   | 44  | ns   |
|                          | Sn to $V_{os}$        | $V_{CC} = 2.0$ V; $V_{EE} = 0$ V     | -   | -   | 315 | ns   |
|                          |                       | $V_{CC} = 4.5$ V; $V_{EE} = 0$ V     | -   | -   | 63  | ns   |
|                          |                       | $V_{CC} = 6.0$ V; $V_{EE} = 0$ V     | -   | -   | 54  | ns   |
|                          |                       | $V_{CC} = 4.5$ V; $V_{EE} = -4.5$ V  | -   | -   | 44  | ns   |

[1]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W):

$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum \{(C_L + C_S) \times V_{CC}^2 \times f_o\}$  where:

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

$\sum \{(C_L + C_S) \times V_{CC}^2 \times f_o\}$  = sum of outputs;

$C_L$  = output load capacitance in pF;

$C_S$  = maximum switch capacitance in pF;

$V_{CC}$  = supply voltage in V.

**Table 11: Dynamic characteristics type 74HCT4053**

Voltages are referenced to GND (ground = 0 V);  $t_r = t_f = 6$  ns;  $C_L = 50$  pF unless otherwise specified; for test circuit see Figure 14.

$V_{is}$  is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

$V_{os}$  is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

| Symbol                              | Parameter                              | Conditions                                                | Min | Typ | Max | Unit |
|-------------------------------------|----------------------------------------|-----------------------------------------------------------|-----|-----|-----|------|
| <b><math>T_{amb} = 25</math> °C</b> |                                        |                                                           |     |     |     |      |
| $t_{PHL}$ ,<br>$t_{PLH}$            | propagation delay $V_{is}$ to $V_{os}$ | $V_{CC} = 4.5$ V; $R_L = \infty$ $\Omega$ ; see Figure 12 |     |     |     |      |
|                                     |                                        | $V_{EE} = 0$ V                                            | -   | 5   | 12  | ns   |
|                                     |                                        | $V_{EE} = -4.5$ V                                         | -   | 4   | 8   | ns   |
| $t_{PZH}$ ,<br>$t_{PZL}$            | turn-ON time                           | $R_L = 1$ k $\Omega$ ; see Figure 13                      |     |     |     |      |
|                                     | $\bar{E}$ to $V_{os}$                  | $V_{CC} = 4.5$ V; $V_{EE} = 0$ V                          | -   | 27  | 48  | ns   |
|                                     |                                        | $V_{CC} = 4.5$ V; $V_{EE} = -4.5$ V                       | -   | 16  | 34  | ns   |
|                                     |                                        | $V_{CC} = 5$ V; $V_{EE} = 0$ V; $C_L = 15$ pF             | -   | 23  | -   | ns   |
|                                     | Sn to $V_{os}$                         | $V_{CC} = 4.5$ V; $V_{EE} = 0$ V                          | -   | 25  | 48  | ns   |
|                                     |                                        | $V_{CC} = 4.5$ V; $V_{EE} = -4.5$ V                       | -   | 16  | 34  | ns   |
|                                     |                                        | $V_{CC} = 5$ V; $V_{EE} = 0$ V; $C_L = 15$ pF             | -   | 21  | -   | ns   |

**Table 11: Dynamic characteristics type 74HCT4053 ...continued**

Voltages are referenced to GND (ground = 0 V);  $t_r = t_f = 6$  ns;  $C_L = 50$  pF unless otherwise specified; for test circuit see Figure 14.

$V_{is}$  is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

$V_{os}$  is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

| Symbol                                                       | Parameter                              | Conditions                                                                  | Min | Typ | Max | Unit |
|--------------------------------------------------------------|----------------------------------------|-----------------------------------------------------------------------------|-----|-----|-----|------|
| $t_{PHZ}$ ,<br>$t_{PLZ}$                                     | turn-OFF time                          | $R_L = 1$ k $\Omega$ ; see Figure 13                                        |     |     |     |      |
|                                                              | $\bar{E}$ to $V_{os}$                  | $V_{CC} = 4.5$ V; $V_{EE} = 0$ V                                            | -   | 24  | 44  | ns   |
|                                                              |                                        | $V_{CC} = 4.5$ V; $V_{EE} = -4.5$ V                                         | -   | 15  | 31  | ns   |
|                                                              |                                        | $V_{CC} = 5$ V; $V_{EE} = 0$ V; $C_L = 15$ pF                               | -   | 20  | -   | ns   |
|                                                              | Sn to $V_{os}$                         | $V_{CC} = 4.5$ V; $V_{EE} = 0$ V                                            | -   | 22  | 44  | ns   |
|                                                              |                                        | $V_{CC} = 4.5$ V; $V_{EE} = -4.5$ V                                         | -   | 15  | 31  | ns   |
|                                                              |                                        | $V_{CC} = 5$ V; $V_{EE} = 0$ V; $C_L = 15$ pF                               | -   | 19  | -   | ns   |
| $C_{PD}$                                                     | power dissipation capacitance          | per switch; $V_I = \text{GND}$ to $(V_{CC} - 1.5 \text{ V})$ <sup>(1)</sup> | -   | 36  | -   | pF   |
| <b><math>T_{amb} = -40</math> °C to <math>+85</math> °C</b>  |                                        |                                                                             |     |     |     |      |
| $t_{PHL}$ ,<br>$t_{PLH}$                                     | propagation delay $V_{is}$ to $V_{os}$ | $V_{CC} = 4.5$ V; $R_L = \infty$ $\Omega$ ; see Figure 12                   |     |     |     |      |
|                                                              |                                        | $V_{EE} = 0$ V                                                              | -   | -   | 15  | ns   |
|                                                              |                                        | $V_{EE} = -4.5$ V                                                           | -   | -   | 10  | ns   |
| $t_{PZH}$ ,<br>$t_{PZL}$                                     | turn-ON time                           | $V_{CC} = 4.5$ V; $R_L = 1$ k $\Omega$ ; see Figure 13                      |     |     |     |      |
|                                                              | $\bar{E}$ to $V_{os}$                  | $V_{EE} = 0$ V                                                              | -   | -   | 60  | ns   |
|                                                              |                                        | $V_{EE} = -4.5$ V                                                           | -   | -   | 43  | ns   |
|                                                              | Sn to $V_{os}$                         | $V_{EE} = 0$ V                                                              | -   | -   | 60  | ns   |
|                                                              |                                        | $V_{EE} = -4.5$ V                                                           | -   | -   | 43  | ns   |
| $t_{PHZ}$ ,<br>$t_{PLZ}$                                     | turn-OFF time                          | $V_{CC} = 4.5$ V; $R_L = 1$ k $\Omega$ ; see Figure 13                      |     |     |     |      |
|                                                              | $\bar{E}$ to $V_{os}$                  | $V_{EE} = 0$ V                                                              | -   | -   | 55  | ns   |
|                                                              |                                        | $V_{EE} = -4.5$ V                                                           | -   | -   | 39  | ns   |
|                                                              | Sn to $V_{os}$                         | $V_{EE} = 0$ V                                                              | -   | -   | 55  | ns   |
|                                                              |                                        | $V_{EE} = -4.5$ V                                                           | -   | -   | 39  | ns   |
| <b><math>T_{amb} = -40</math> °C to <math>+125</math> °C</b> |                                        |                                                                             |     |     |     |      |
| $t_{PHL}$ ,<br>$t_{PLH}$                                     | propagation delay $V_{is}$ to $V_{os}$ | $V_{CC} = 4.5$ V; $R_L = \infty$ $\Omega$ ; see Figure 12                   |     |     |     |      |
|                                                              |                                        | $V_{EE} = 0$ V                                                              | -   | -   | 18  | ns   |
|                                                              |                                        | $V_{EE} = -4.5$ V                                                           | -   | -   | 12  | ns   |
| $t_{PZH}$ ,<br>$t_{PZL}$                                     | turn-ON time                           | $V_{CC} = 4.5$ V; $R_L = 1$ k $\Omega$ ; see Figure 13                      |     |     |     |      |
|                                                              | $\bar{E}$ to $V_{os}$                  | $V_{EE} = 0$ V                                                              | -   | -   | 72  | ns   |
|                                                              |                                        | $V_{EE} = -4.5$ V                                                           | -   | -   | 51  | ns   |
|                                                              | Sn to $V_{os}$                         | $V_{EE} = 0$ V                                                              | -   | -   | 72  | ns   |
|                                                              |                                        | $V_{EE} = -4.5$ V                                                           | -   | -   | 51  | ns   |

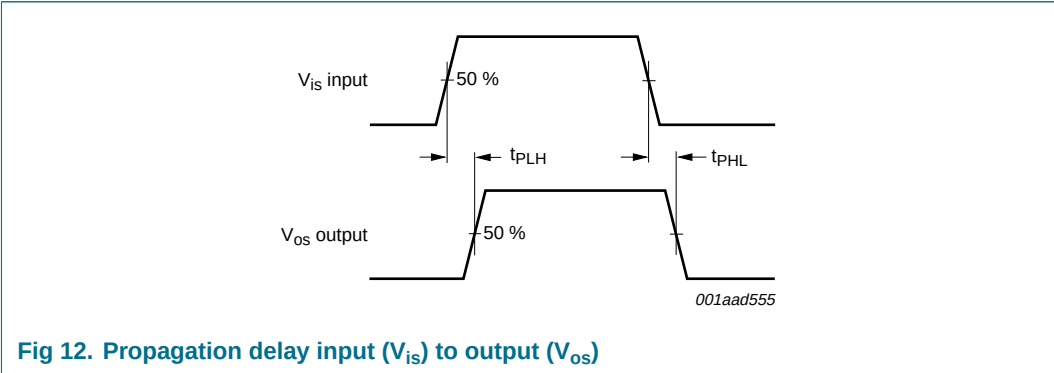
**Table 11: Dynamic characteristics type 74HCT4053 ...continued**  
Voltages are referenced to GND (ground = 0 V);  $t_r = t_f = 6\text{ ns}$ ;  $C_L = 50\text{ pF}$  unless otherwise specified; for test circuit see Figure 14.

$V_{is}$  is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.  
 $V_{os}$  is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

| Symbol                   | Parameter             | Conditions                                                         | Min | Typ | Max | Unit |
|--------------------------|-----------------------|--------------------------------------------------------------------|-----|-----|-----|------|
| $t_{PHZ}$ ,<br>$t_{PLZ}$ | turn-OFF time         | $V_{CC} = 4.5\text{ V}$ ; $R_L = 1\text{ k}\Omega$ ; see Figure 13 |     |     |     |      |
|                          | $\bar{E}$ to $V_{os}$ | $V_{EE} = 0\text{ V}$                                              | -   | -   | 66  | ns   |
|                          |                       | $V_{EE} = -4.5\text{ V}$                                           | -   | -   | 47  | ns   |
|                          | Sn to $V_{os}$        | $V_{EE} = 0\text{ V}$                                              | -   | -   | 66  | ns   |
|                          |                       | $V_{EE} = -4.5\text{ V}$                                           | -   | -   | 47  | ns   |

- [1]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ):  
 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum\{(C_L + C_S) \times V_{CC}^2 \times f_o\}$  where:  
 $f_i$  = input frequency in MHz;  
 $f_o$  = output frequency in MHz;  
 $\sum\{(C_L + C_S) \times V_{CC}^2 \times f_o\}$  = sum of outputs;  
 $C_L$  = output load capacitance in pF;  
 $C_S$  = maximum switch capacitance in pF;  
 $V_{CC}$  = supply voltage in V.

13. Waveforms



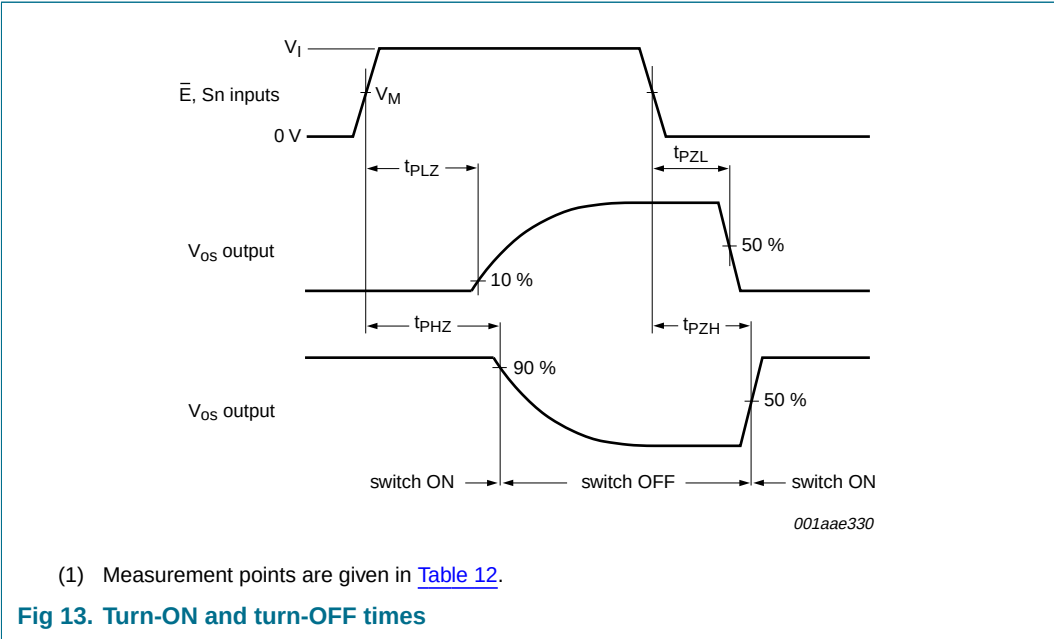


Table 12: Measurement points

| Type      | Input       |
|-----------|-------------|
|           | $V_M$       |
| 74HC4053  | $0.5V_{CC}$ |
| 74HCT4053 | 1.3 V       |

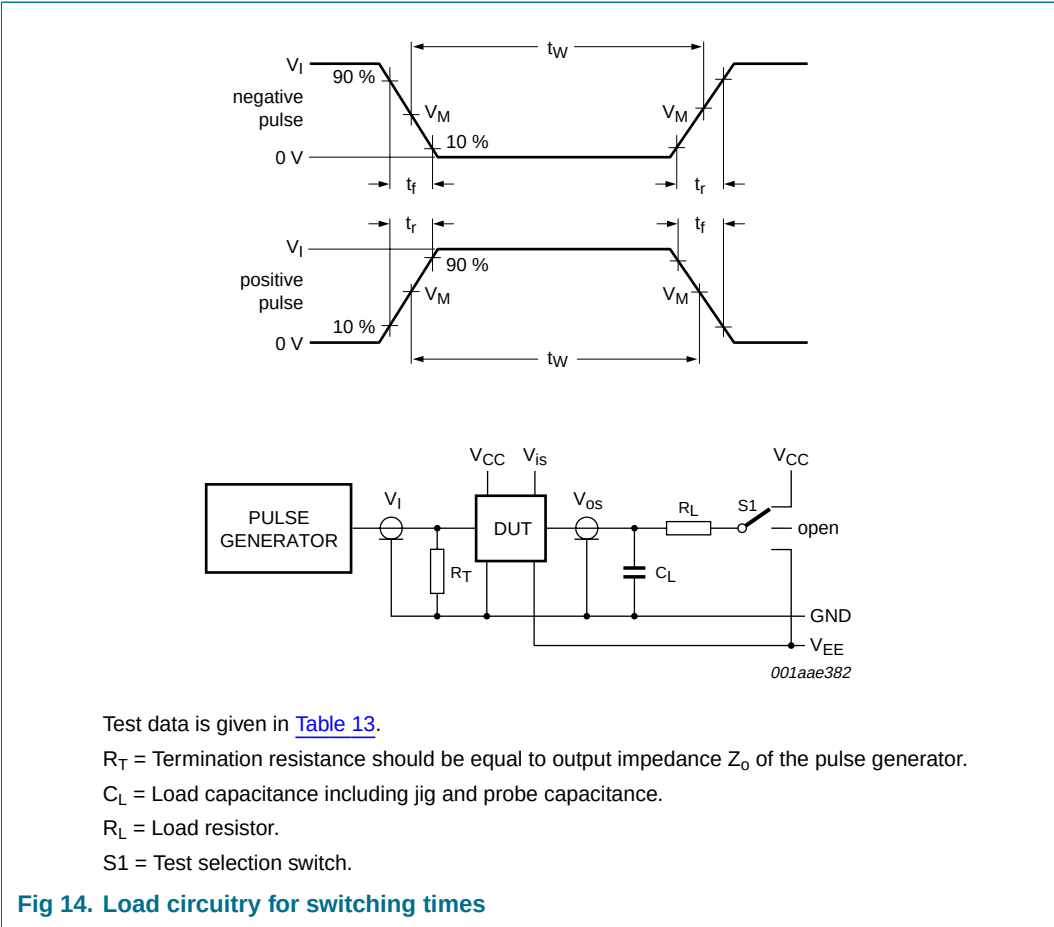


Table 13: Test data

| Test                                | Input          |                 |                                 |       | Load           |                | S1 position     |
|-------------------------------------|----------------|-----------------|---------------------------------|-------|----------------|----------------|-----------------|
|                                     | V <sub>I</sub> | V <sub>is</sub> | t <sub>r</sub> , t <sub>f</sub> |       | C <sub>L</sub> | R <sub>L</sub> |                 |
|                                     |                |                 | at f <sub>max</sub>             | other |                |                |                 |
| t <sub>PHL</sub> , t <sub>PLH</sub> | [1]            | pulse           | < 2 ns                          | 6 ns  | 15 pF, 50 pF   | 1 kΩ           | open            |
| t <sub>PZH</sub> , t <sub>PHZ</sub> | [1]            | V <sub>CC</sub> | < 2 ns                          | 6 ns  | 15 pF, 50 pF   | 1 kΩ           | V <sub>EE</sub> |
| t <sub>PZL</sub> , t <sub>PLZ</sub> | [1]            | V <sub>EE</sub> | < 2 ns                          | 6 ns  | 15 pF, 50 pF   | 1 kΩ           | V <sub>CC</sub> |

[1]  $V_I$  values:  
a) For 74HC4053:  $V_I = V_{CC}$ .  
b) For 74HCT4053:  $V_I = 3$  V.

## 14. Additional dynamic characteristics

**Table 14: Additional dynamic characteristics 74HC4053 and 74HCT4053**

$GND = 0\text{ V}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .

$V_{is}$  is the input voltage at an nYn or nZ terminal, whichever is assigned as an input.

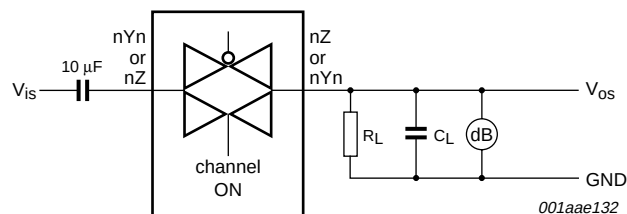
$V_{os}$  is the output voltage at an nYn or nZ terminal, whichever is assigned as an output.

| Symbol               | Parameter                                   | Conditions                                                                                                                         | Min | Typ  | Max | Unit |
|----------------------|---------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------|-----|------|-----|------|
| $d_{sin}$            | sine wave distortion                        | $R_L = 10\text{ k}\Omega$ ; $C_L = 50\text{ pF}$ ; see <a href="#">Figure 15</a>                                                   |     |      |     |      |
|                      |                                             | $f_i = 1\text{ kHz}$                                                                                                               |     |      |     |      |
|                      |                                             | $V_{CC} = 2.25\text{ V}$ ; $V_{EE} = -2.25\text{ V}$ ; $V_{is} = 4.0\text{ V (p-p)}$                                               | -   | 0.04 | -   | %    |
|                      |                                             | $V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$ ; $V_{is} = 8.0\text{ V (p-p)}$                                                 | -   | 0.02 | -   | %    |
|                      |                                             | $f_i = 10\text{ kHz}$                                                                                                              |     |      |     |      |
|                      |                                             | $V_{CC} = 2.25\text{ V}$ ; $V_{EE} = -2.25\text{ V}$ ; $V_{is} = 4.0\text{ V (p-p)}$                                               | -   | 0.12 | -   | %    |
| $\alpha_{(OFF)(ft)}$ | OFF-state feed-through attenuation          | $R_L = 600\text{ }\Omega$ ; $C_L = 50\text{ pF}$ ; $f_i = 1\text{ MHz}$ ; see <a href="#">Figure 16</a>                            |     |      |     |      |
|                      |                                             | $V_{CC} = 2.25\text{ V}$ ; $V_{EE} = -2.25\text{ V}$                                                                               | -   | -50  | -   | dB   |
|                      |                                             | $V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$                                                                                 | -   | -50  | -   | dB   |
| $V_{ct(sw-sw)}$      | crosstalk between switches                  | $R_L = 600\text{ }\Omega$ ; $C_L = 50\text{ pF}$ ; $f_i = 1\text{ MHz}$ ; see <a href="#">Figure 17</a>                            |     |      |     |      |
|                      |                                             | $V_{CC} = 2.25\text{ V}$ ; $V_{EE} = -2.25\text{ V}$                                                                               | -   | -60  | -   | dB   |
|                      |                                             | $V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$                                                                                 | -   | -60  | -   | dB   |
| $V_{ct(d-sw)}$       | crosstalk between digital inputs and switch | $V_{CC} = 4.5\text{ V}$ ; $R_L = 600\text{ k}\Omega$ ; $C_L = 50\text{ pF}$ ; $f_i = 1\text{ MHz}$ ; see <a href="#">Figure 18</a> |     |      |     |      |
|                      |                                             | $V_{EE} = 0\text{ V}$                                                                                                              | -   | 110  | -   | mV   |
|                      |                                             | $V_{EE} = -4.5\text{ V}$                                                                                                           | -   | 220  | -   | mV   |
| $f_{(-3dB)}$         | -3 dB frequency response                    | $R_L = 50\text{ }\Omega$ ; $C_L = 10\text{ pF}$ ; see <a href="#">Figure 19</a>                                                    |     |      |     |      |
|                      |                                             | $V_{CC} = 2.25\text{ V}$ ; $V_{EE} = -2.25\text{ V}$                                                                               | -   | 160  | -   | MHz  |
|                      |                                             | $V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$                                                                                 | -   | 170  | -   | MHz  |

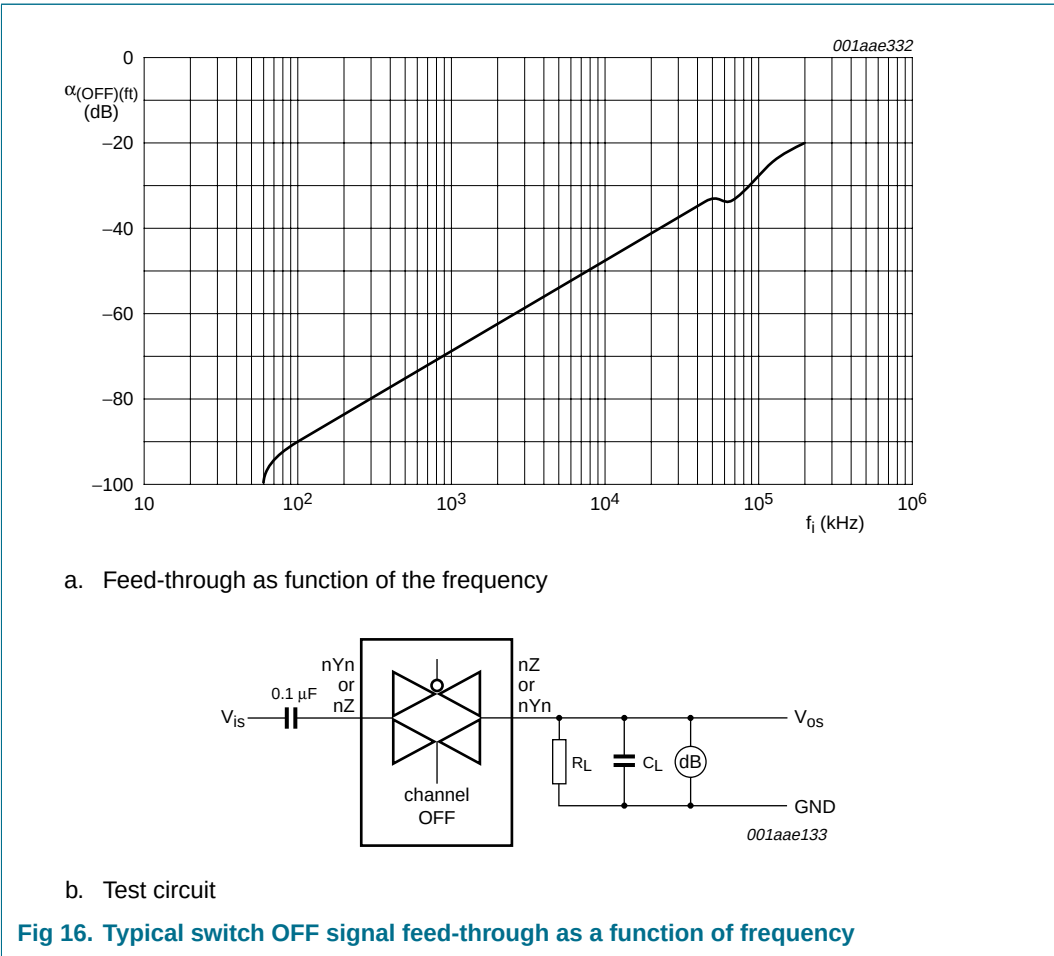
[1] Adjust input voltage  $V_{is}$  to 0 dBm level (0 dBm = 1 mW into 600  $\Omega$ ).

[2] Control input  $\bar{E}$  or Sn, with square-wave between  $V_{CC}$  and GND.

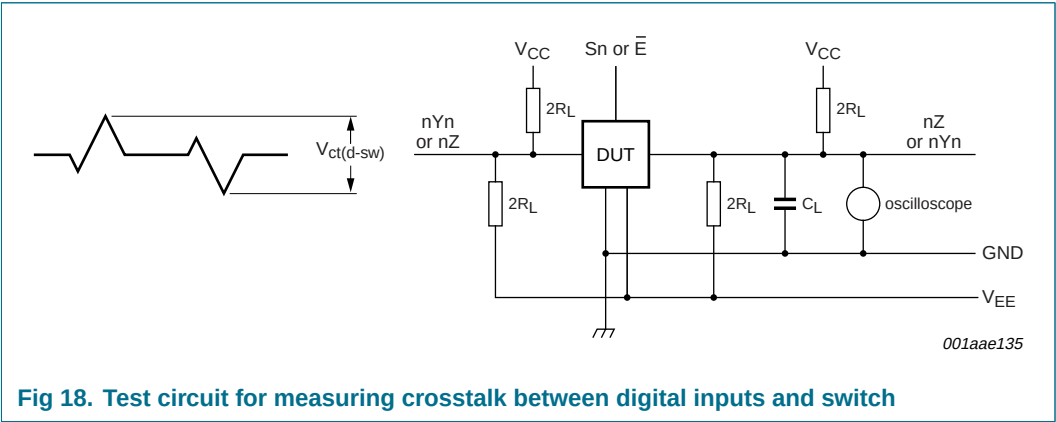
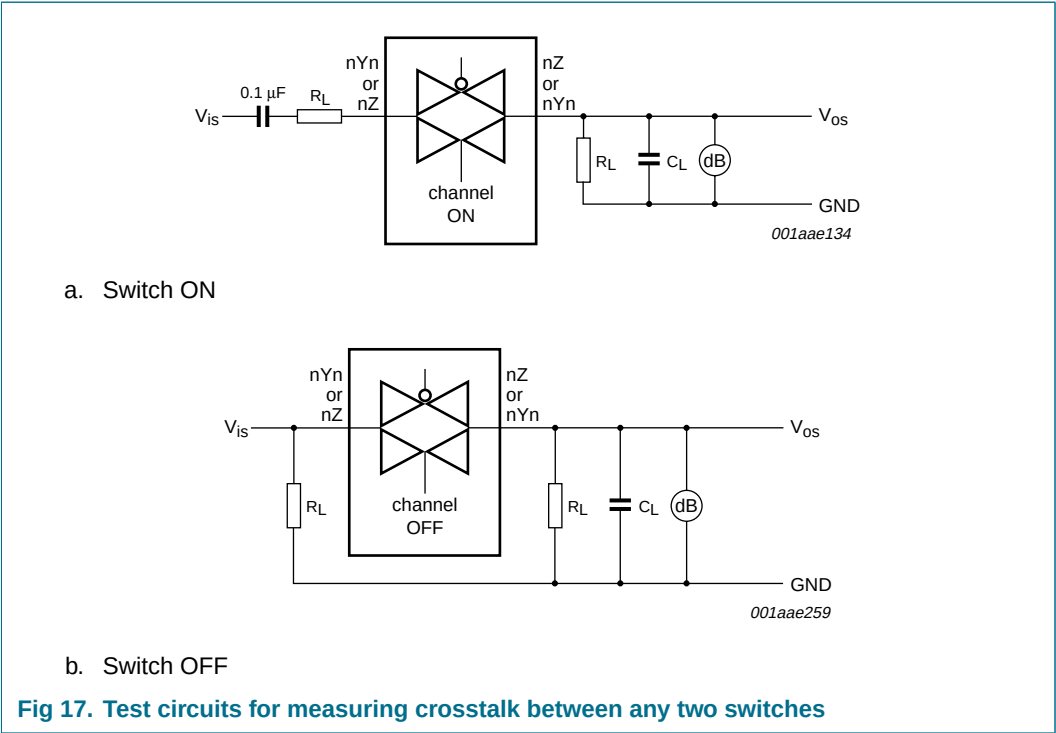
[3] Adjust input voltage  $V_{is}$  to 0 dBm level at  $V_{os}$  for 1 MHz (0 dBm = 1 mW into 50  $\Omega$ ).

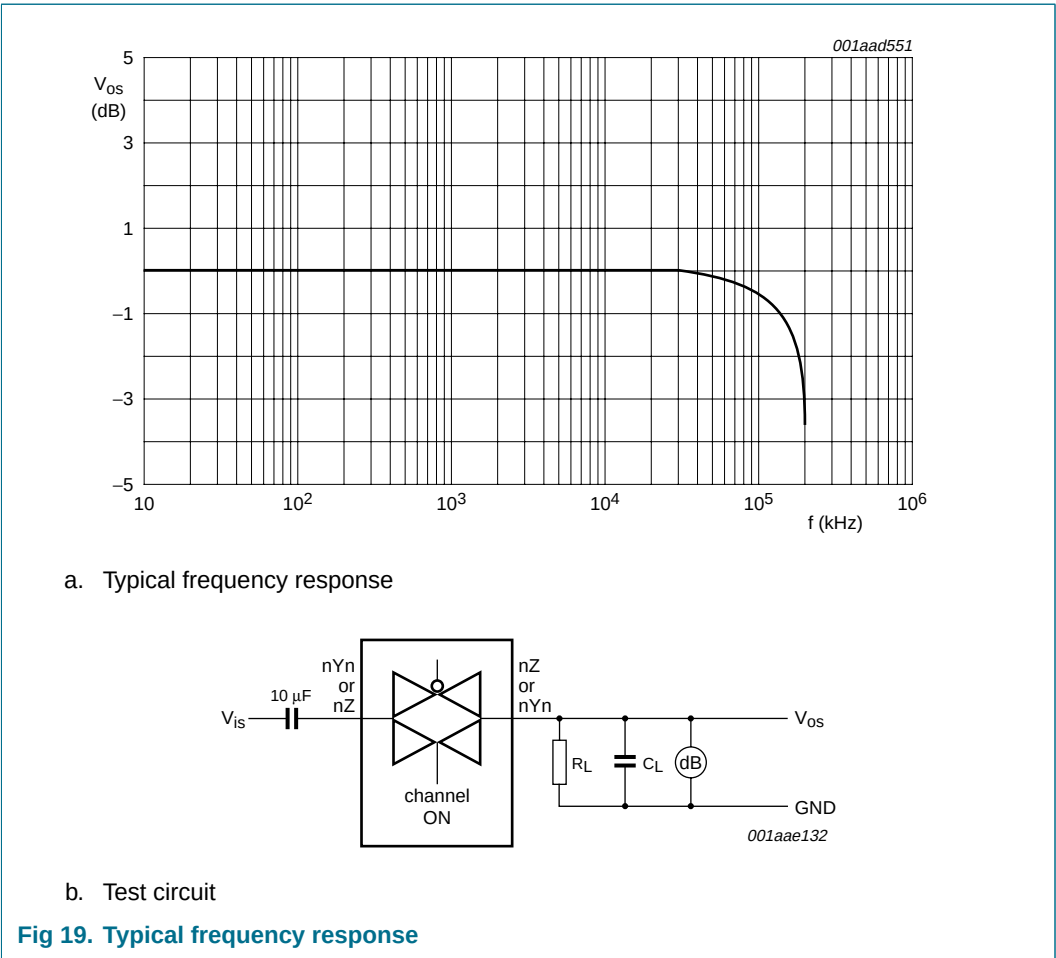


**Fig 15. Test circuit for measuring sine wave distortion**









15. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4

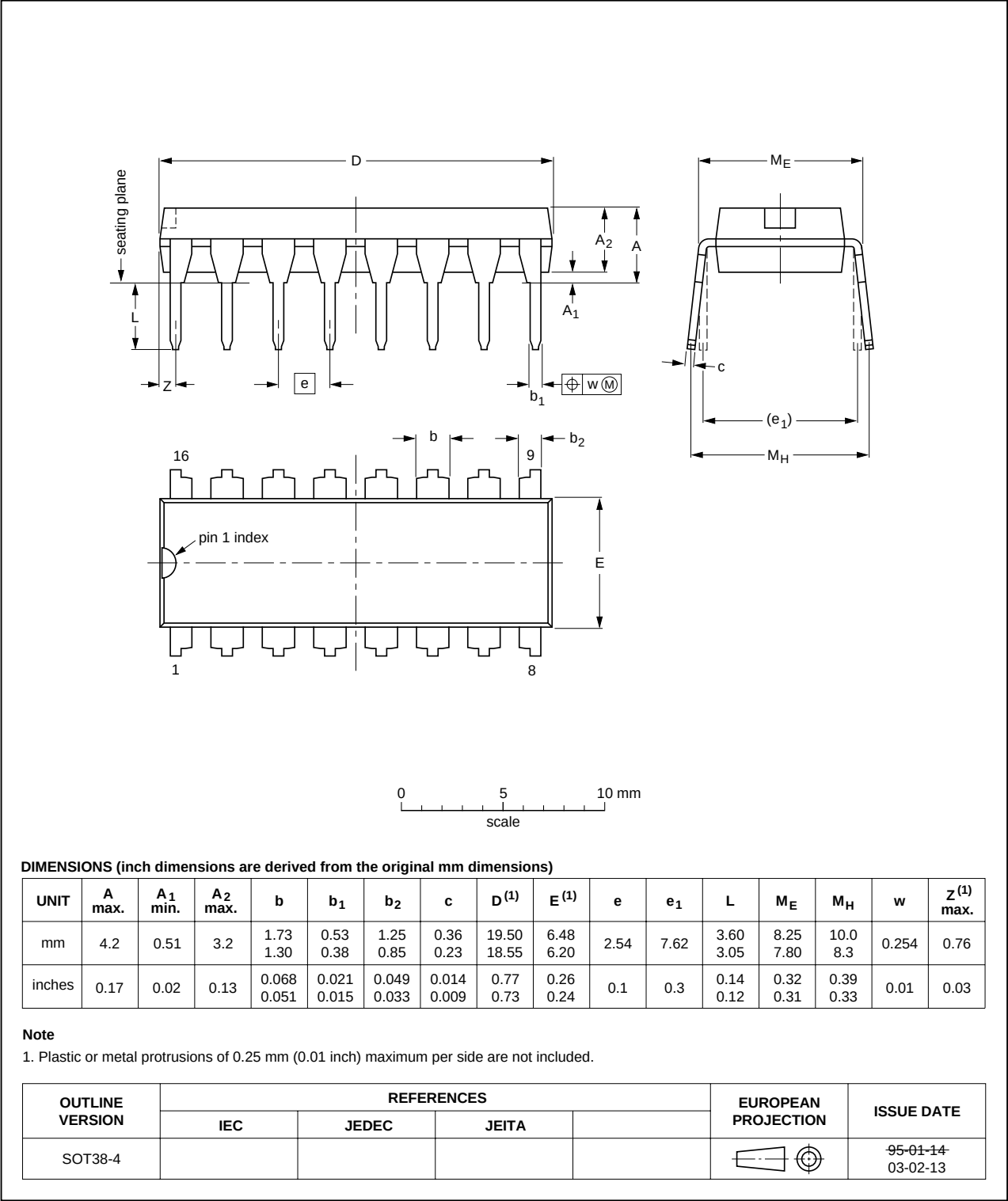
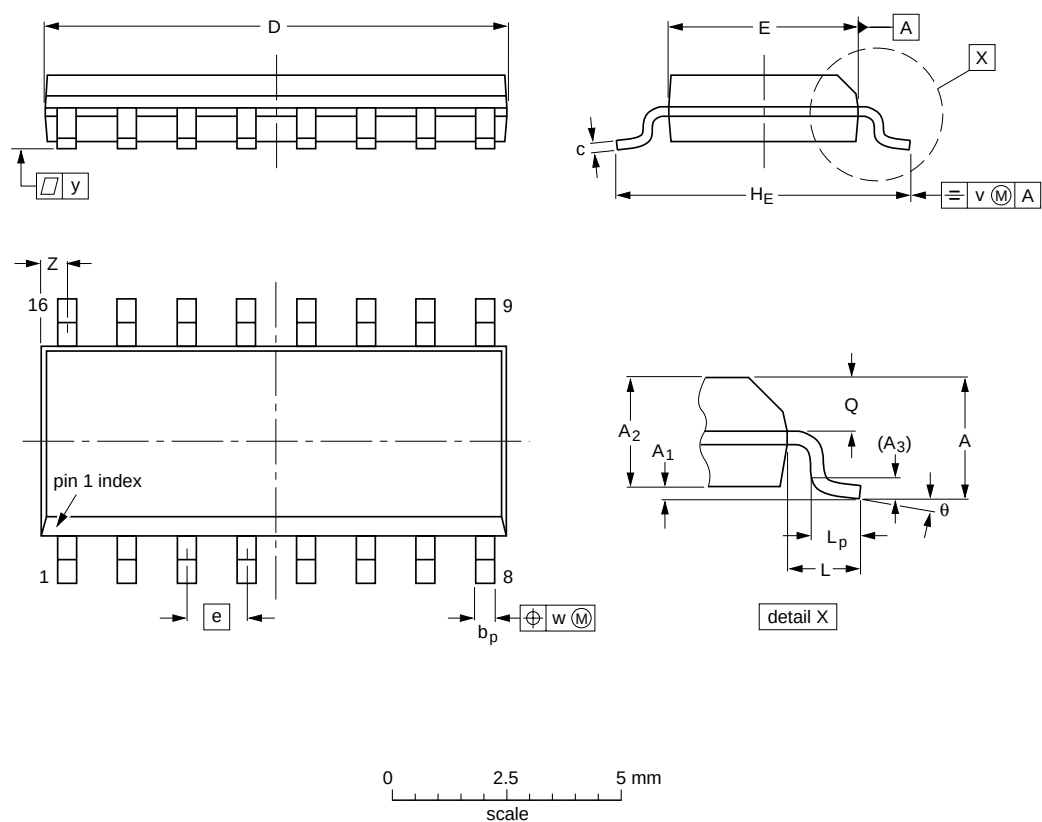


Fig 20. Package outline SOT38-4 (DIP16)

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

| UNIT   | A<br>max. | A <sub>1</sub> | A <sub>2</sub> | A <sub>3</sub> | b <sub>p</sub> | c                | D <sup>(1)</sup> | E <sup>(1)</sup> | e    | H <sub>E</sub> | L     | L <sub>p</sub> | Q              | v    | w    | y     | z <sup>(1)</sup> | θ        |
|--------|-----------|----------------|----------------|----------------|----------------|------------------|------------------|------------------|------|----------------|-------|----------------|----------------|------|------|-------|------------------|----------|
| mm     | 1.75      | 0.25<br>0.10   | 1.45<br>1.25   | 0.25           | 0.49<br>0.36   | 0.25<br>0.19     | 10.0<br>9.8      | 4.0<br>3.8       | 1.27 | 6.2<br>5.8     | 1.05  | 1.0<br>0.4     | 0.7<br>0.6     | 0.25 | 0.25 | 0.1   | 0.7<br>0.3       | 8°<br>0° |
| inches | 0.069     | 0.010<br>0.004 | 0.057<br>0.049 | 0.01           | 0.019<br>0.014 | 0.0100<br>0.0075 | 0.39<br>0.38     | 0.16<br>0.15     | 0.05 | 0.244<br>0.228 | 0.041 | 0.039<br>0.016 | 0.028<br>0.020 | 0.01 | 0.01 | 0.004 | 0.028<br>0.012   |          |

**Note**  
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

| OUTLINE<br>VERSION | REFERENCES |        |       |  | EUROPEAN<br>PROJECTION | ISSUE DATE           |
|--------------------|------------|--------|-------|--|------------------------|----------------------|
|                    | IEC        | JEDEC  | JEITA |  |                        |                      |
| SOT109-1           | 076E07     | MS-012 |       |  |                        | 99-12-27<br>03-02-19 |

Fig 21. Package outline SOT109-1 (SO16)

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1

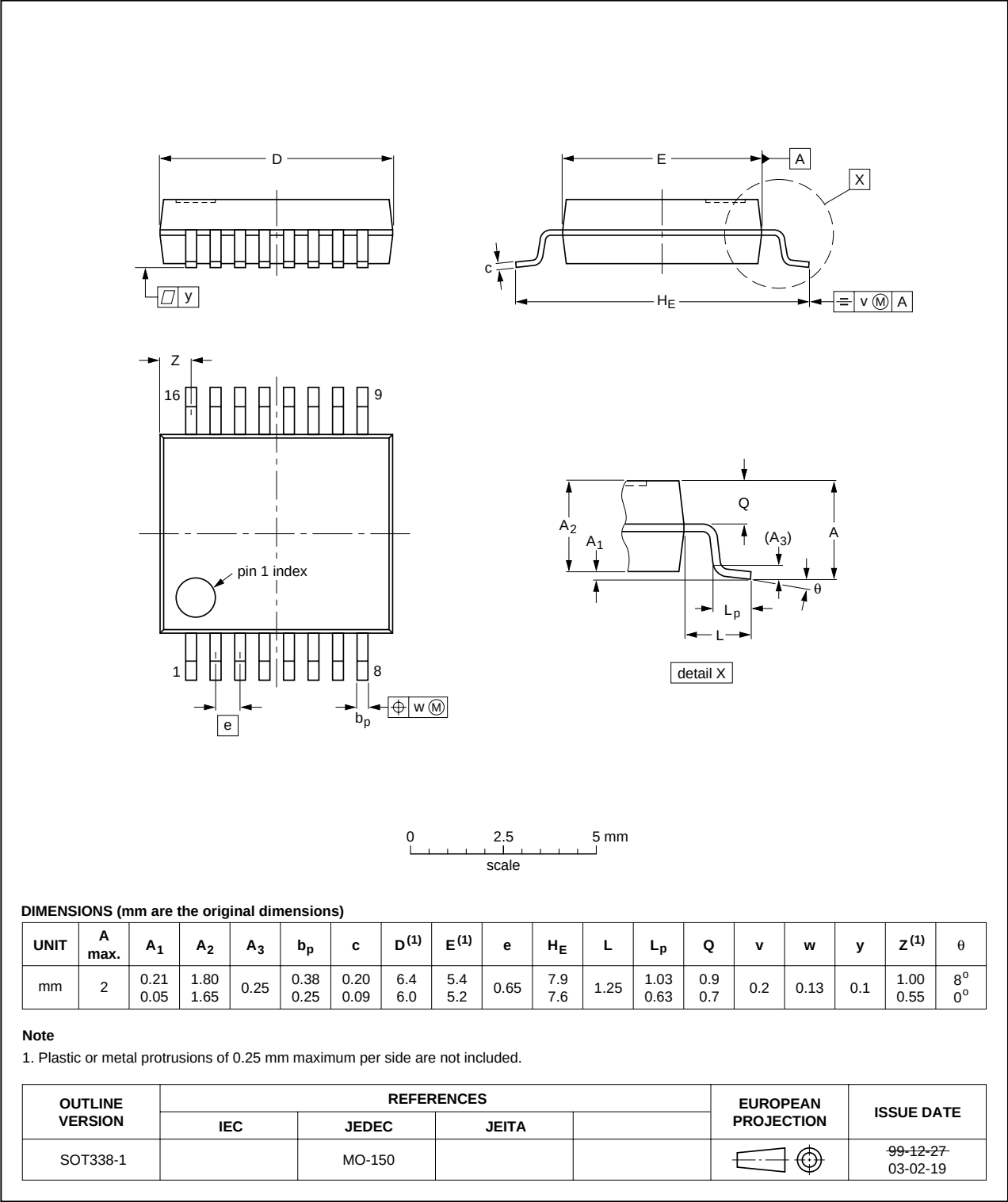
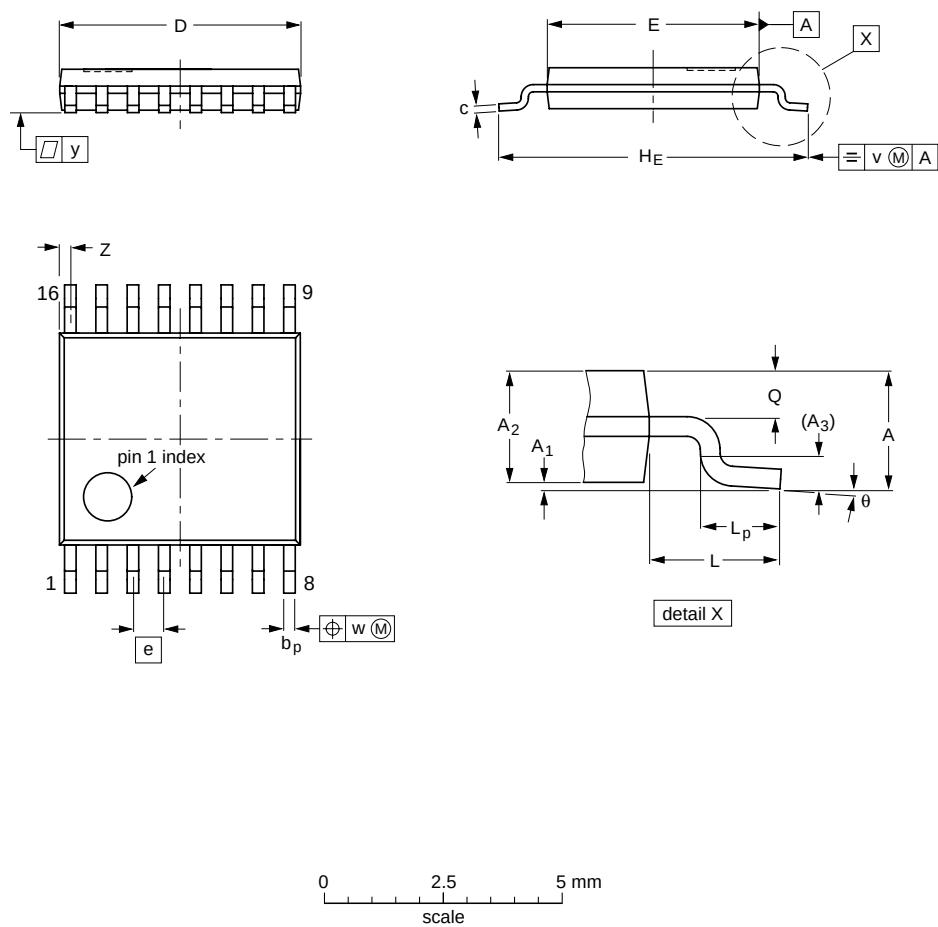


Fig 22. Package outline SOT338-1 (SSOP16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



DIMENSIONS (mm are the original dimensions)

| UNIT | A<br>max. | A <sub>1</sub> | A <sub>2</sub> | A <sub>3</sub> | b <sub>p</sub> | c          | D <sup>(1)</sup> | E <sup>(2)</sup> | e    | H <sub>E</sub> | L | L <sub>p</sub> | Q          | v   | w    | y   | z <sup>(1)</sup> | θ        |
|------|-----------|----------------|----------------|----------------|----------------|------------|------------------|------------------|------|----------------|---|----------------|------------|-----|------|-----|------------------|----------|
| mm   | 1.1       | 0.15<br>0.05   | 0.95<br>0.80   | 0.25           | 0.30<br>0.19   | 0.2<br>0.1 | 5.1<br>4.9       | 4.5<br>4.3       | 0.65 | 6.6<br>6.2     | 1 | 0.75<br>0.50   | 0.4<br>0.3 | 0.2 | 0.13 | 0.1 | 0.40<br>0.06     | 8°<br>0° |

- Notes
1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

| OUTLINE<br>VERSION | REFERENCES |        |       |  | EUROPEAN<br>PROJECTION | ISSUE DATE           |
|--------------------|------------|--------|-------|--|------------------------|----------------------|
|                    | IEC        | JEDEC  | JEITA |  |                        |                      |
| SOT403-1           |            | MO-153 |       |  |                        | 99-12-27<br>03-02-18 |

Fig 23. Package outline SOT403-1 (TSSOP16)

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

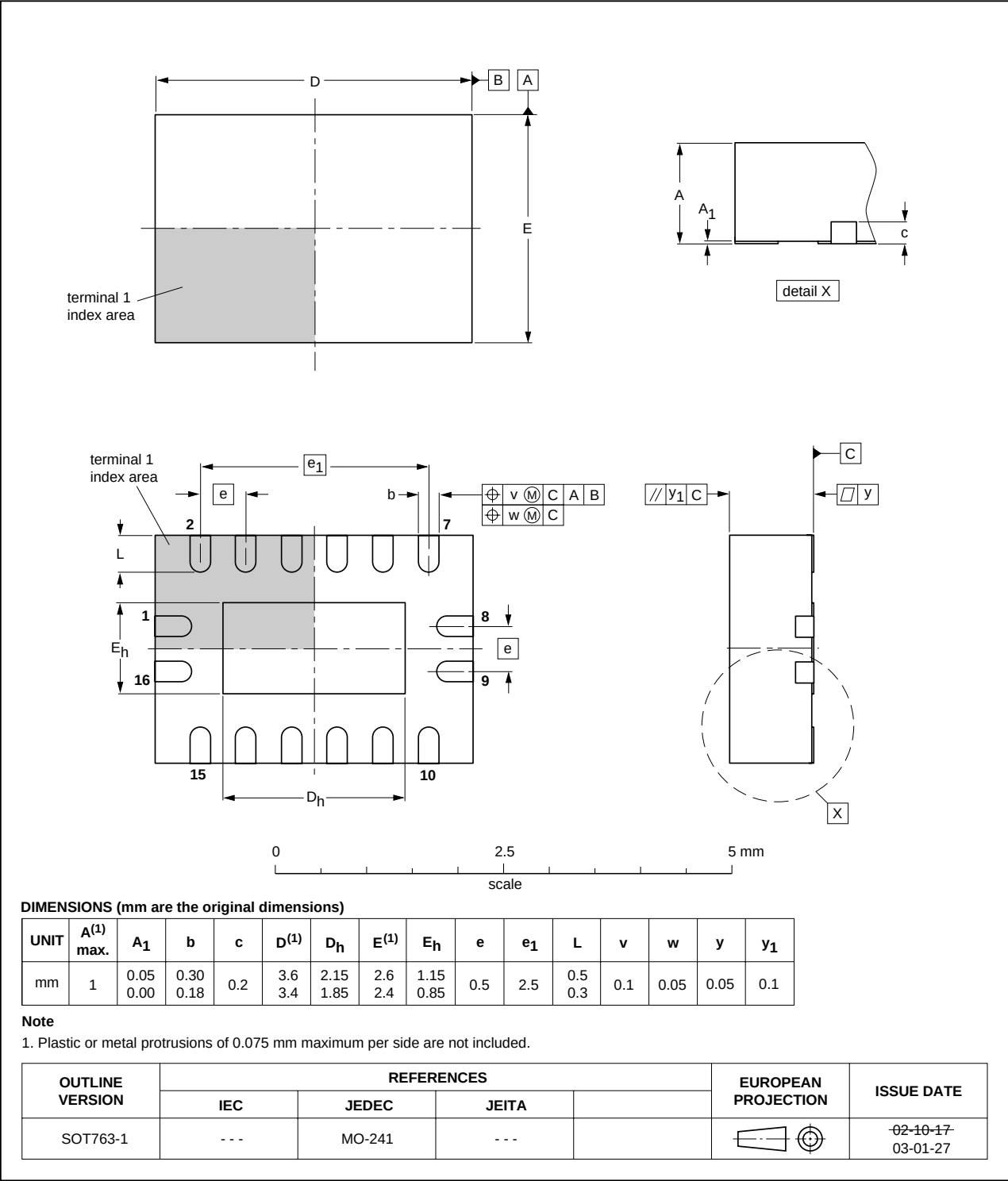


Fig 24. Package outline SOT763-1 (DHVQFN16)

## 16. Abbreviations

Table 15: Abbreviations

| Acronym | Description                             |
|---------|-----------------------------------------|
| CMOS    | Complementary Metal Oxide Semiconductor |
| HBM     | Human Body Model                        |
| ESD     | ElectroStatic Discharge                 |
| MM      | Machine Model                           |
| DUT     | Device Under Test                       |

## 17. Revision history

Table 16: Revision history

| Document ID        | Release date                                                                                                                                                                                                                                                                                                                                                                                                             | Data sheet status     | Change notice | Doc. number | Supersedes         |
|--------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------|---------------|-------------|--------------------|
| 74HC_HCT4053_4     | 20060509                                                                                                                                                                                                                                                                                                                                                                                                                 | Product data sheet    | -             | -           | 74HC_HCT4053_3     |
| Modifications:     | <ul style="list-style-type: none"><li><a href="#">Section 5 "Ordering information"</a>: errors corrected, type numbers in wrong order and SOT38-4 is the package for types 74HC4053N and 74HCT4053N</li></ul>                                                                                                                                                                                                            |                       |               |             |                    |
| 74HC_HCT4053_3     | 20060315                                                                                                                                                                                                                                                                                                                                                                                                                 | Product data sheet    | -             | -           | 74HC_HCT4053_CNV_2 |
| Modifications:     | <ul style="list-style-type: none"><li>The format of this data sheet has been redesigned to comply with the new presentation and information standard of Philips Semiconductors.</li><li>Added type numbers 74HC4053BQ and 74HCT4053BQ (DHVQFN16) package to <a href="#">Section 5 "Ordering information"</a>, <a href="#">Section 7 "Pinning information"</a> and <a href="#">Section 15 "Package outline"</a></li></ul> |                       |               |             |                    |
| 74HC_HCT4053_CNV_2 | 19901201                                                                                                                                                                                                                                                                                                                                                                                                                 | Product specification | -             | -           | -                  |



## 18. Data sheet status

| Level | Data sheet status <sup>[1]</sup> | Product status <sup>[2] [3]</sup> | Definition                                                                                                                                                                                                                                                                                     |
|-------|----------------------------------|-----------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| I     | Objective data                   | Development                       | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.                                                                                                    |
| II    | Preliminary data                 | Qualification                     | This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.             |
| III   | Product data                     | Production                        | This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN). |

[1] Please consult the most recently issued data sheet before initiating or completing a design.

[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL <http://www.semiconductors.philips.com>.

[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

## 19. Definitions

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

**Limiting values definition** — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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